S1D15E06 Series

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1. DESCRIPTION

The S1D15E06 series is a single chip MLS driver for dot matrix liquid crystal displays which can be directly connected to the microcomputer bus. It accepts the 8-bit parallel or serial display data from the microcomputer to store the data in the on-chip display data RAM, and issues liquid crystal drive signals independently of the microcomputer.

The S1D15E06 series provides both 4 gray-scale display and binary display. It incorporates a display data RAM $(132 \times 160 \times 2 \text{ bits})$. In the case of 4 gray-scale display, 2 bits of the on-chip RAM respond to one-dot pixels, while in the case of binary display, 1 bit of the on-chip RAM respond to one-dot pixels.

The S1D15E06 series features 132 common output circuits and 160 segment output circuits. A single chip provides a display of 10 characters by 8 lines with 132 × 160 dots (16×16 dots) and display of 13 characters by 11 lines by the 12×12 dot-character font.

Display data RAM read/write operations do not require operation clock from outside, thereby ensuring operation with the minimum current consumption. Furthermore, it incorporates a LCD-drive power supply characterized by low power consumption and a CR oscillator circuit for display clock; therefore, the display system of a handy and high-performance instrument can be realized by use of the minimum current consumption and minimum chip configuration.

2. FEATURES

• Direct RAM data display by display data RAM

• 4 gray-scale display

(Normally white in normal display mode) RAM bit data (high order and low order)

(1,1): gray-scale 3, black

(1,0): gray-scale 2

(0,1): gray-scale 1

(0,0): gray-scale 0, white

· Binary display

(Normally white display is in normal mode) RAM bit data

"1": On and black

"0": Off and white

• RAM capacity

 $132 \times 160 \times 2 = 42,240$ bits

• Liquid crystal drive circuit

132 common outputs and 160 segment outputs

- High-speed 8-bit MPU interface (directly connectable to the MPUs of both 80/68 series) /serial interface possible
- A variety of command functions
 Area scroll display, partial display, n-line reversal,
 display data RAM address control, contrast control,
 display ON/OFF, display normal/reverse rotation,
 display all lighting ON/OFF, liquid crystal drive
 power supply circuit control, display clock built-in
 oscillator circuit control
- Lower power MLS drive technology Built-in high precision voltage regulation function
- High precision CR oscillator circuit incorporated
- Very low power consumption
- Power supply

Logic power supply: VDD - VSS = 1.7 to 3.6 V Liquid crystal drive power supply:

 $V_3 - V_{SS} = 3.4 \text{ to } 14.0 \text{ V } (S1D15E06D01****),$

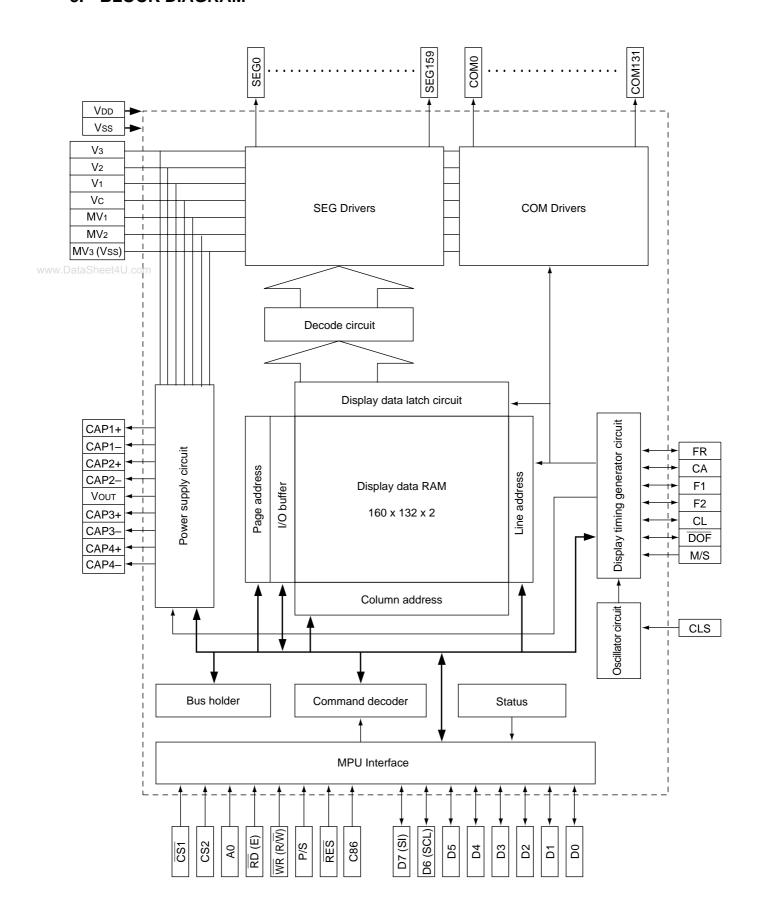
 $V_3 - V_{SS} = 3.4 \text{ to } 16.0 \text{ V } (S1D15E06D03****)$

- Wide operation temperature range: -40 to 85°C
- CMOS process
- Shipping form: Bare chips, TCP
- Light and radiation proof measures are not taken in designing.

Series specifications

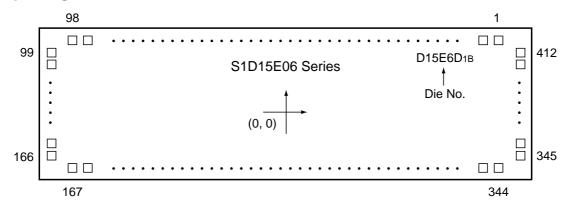
Product name	Bias	LCD driving voltage range	Duty (Max.)	Form of shipping	Chip thickness
S1D15E06D01B000	1/7	3.4V~14.0V	1/132	Bare chip	0.400mm
S1D15E06D03B000	1/7	3.4V~16.0V	1/132	Bare chip	0.400mm
S1D15E06D01E000	1/7	3.4V~14.0V	1/132	Bare chip	0.625mm
S1D15E06D03E000	1/7	3.4V~16.0V	1/132	Bare chip	0.625mm
S1D15E06T00A00A	1/7	3.4V~14.0V	1/132	TCP	_

3. BLOCK DIAGRAM



4. PIN ASSIGNMENT

4.1 Chip Assignment



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	lta	Size	е	l lmit		
	Item	X	Υ	Unit		
	Chip size	10.26 ×	3.98	mm		
	Chip thickness	0.4/0.6	0.4/0.625			
	Bump pitch	50 (M	in.)	μm		
Bump size	PAD No.1 to 98	70 ×	92	μm		
	PAD No.99 to 166, 345 to 412	116 ×	33	μm		
	PAD No.167 to 175, 336 to 344	61 ×	61	μm		
	PAD No.176 to 335	33 ×	116	μm		
	Bump height	22.5 (T	yp.)	μm		

4.2 Alignment mark

Alignment coordinate

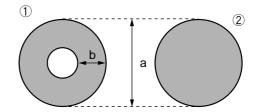
① (–4761.4, 1830.0) μm

② (4926.0, -1819.1) µm

Mark size

 $a=80\;\mu m$

 $b = 20 \mu m$



4.3 Pad Center Coordinates

Unit: μm

Г		D:			D.A.D.	D:			PAD Pin			
	PAD No.	Pin Name	X	Y	PAD No.	Pin Name	X	Y	No.	Name	Х	Y
	1	NC	4494	1830	51	D4	-170	1830	101	COM64	-4958	1575
	2	NC	4402		52	D5	-262		102	COM63		1525
	3	TEST0	4310		53	D6, SCL	-354		103	COM62		1475
	4	TEST1	4218		54	D7, SI	-446		104	COM61		1425
	5	TEST2	4126		55	Vss	-538		105	COM60		1375
	6	TEST3	4034		56	Vss	-630		106	COM59		1325
	7	TEST4	3942		57	Vss	-722		107	COM58		1275
	8	TEST5	3850		58	Vdd	-814		108	COM57		1225
	9	Vss	3742		59	Vdd	-906		109	COM56		1175
	10	TEST6	3634		60	Vdd	-998		110	COM55		1125
.Da	11 staSheet	TEST7	3542		61	Vout	-1090		111	COM54		1075
	12	TEST8	3450		62	Vout	-1182		112	COM53		1025
	13	TEST9	3358		63	CAP1+	-1274		113	COM52		975
	14	TEST10	3266		64	CAP1+	-1366		114	COM51		925
	15	TEST11	3174		65	CAP1-	-1458		115	COM50		875
	16	TEST12	3082		66	CAP1-	-1550		116	COM49		825
	17	TEST13	2990		67	CAP2-	-1642		117	COM48		775
	18	TEST14	2898		68	CAP2-	-1734		118	COM47		725
	19	TEST15	2806		69	CAP2+	-1826		119	COM46		675
	20	TEST16	2714		70	CAP2+	-1918		120	COM45		625
	21	TEST17	2622		71	CAP3+	-2010		121	COM44		575
	22	TEST18	2530		72	CAP3+	-2102		122	COM43		525
	23	Vss	2422		73	CAP3-	-2194		123	COM42		475
	24	FR	2314		74	CAP3-	-2286		124	COM41		425
	25	_CL_	2222		75	CAP4-	-2378		125	COM40		375
	26	DOF	2130		76	CAP4-	-2470		126	COM39		325
	27	F1	2038		77	CAP4+	-2562		127	COM38		275
	28	F2	1946		78	CAP4+	-2654		128	COM37		225
	29	CA	1854		79	V3	-2746		129	COM36		175
	30	Vss	1762		80	V3	-2838		130	COM35		125
	31	TEST	1670		81	V2	-2930		131	COM34		75
	32	CS1	1578		82	V2	-3022		132	COM33		25
	33	RES	1486		83	V1	-3114		133	COM32		-25
	34	A0	1394		84	V1	-3206		134	COM31		-75
	35	W <u>R,</u> R/W	1302		85	Vc	-3298		135	COM30		-125
	36	RD, E	1210		86	Vc	-3390		136	COM29		-175
	37	CS2	1118		87	MV1	-3482		137	COM28		-225
	38	Vdd	1026		88	MV1	-3574		138	COM27		-275
	39	M/S	934		89	MV2	-3666		139	COM26		-325
	40	Vss	842		90	MV2	-3758		140	COM25		-375
	41	CLS	750		91	МVз	-3850		141	COM24		-425
	42	Vdd	658		92	МVз	-3942		142	COM23		-475
	43	C86	566		93	CPP+	-4034		143	COM22		-525
	44	Vss	474		94	CPP-	-4126		144	COM21		-575
	45	P/S	382		95	CPM+	-4218		145	COM20		-625
	46	Vdd	290		96	CPM-	-4310		146	COM19		-675
	47	D0	198		97	NC	-4402		147	COM18		-725
	48	D1	106		98	NC	-4494	♦	148	COM17		-775
	49	D2	14		99	NC	-4958	1675	149	COM16		-825
	50	D3	-78	+	100	COM65		1625	150	COM15	♦	-875

Unit: µm

											`	Jnit: μm
	PAD	Pin	X	Υ	PAD	Pin	Х	Υ	PAD	Pin	Х	Υ
	No.	Name	_ ^	1	No.	Name	^	1	No.	Name	^	T
	151	COM14	-4958	-925	201	SEG25	-2725	-1818	251	SEG75	-225	-1818
	152	COM13	1 1	-975	202	SEG26	-2675		252	SEG76	-175	
	153	COM12		-1025	203	SEG27	-2625		253	SEG77	-125	
	154	COM11		-1075	204	SEG28	-2575		254	SEG78	-75	
	155	COM10		-1125	205	SEG29	-2525		255	SEG79	-25	
	156	COM9		-1175	206	SEG30	-2475		256	SEG80	25	
	157	COM8		-1225	207	SEG31	-2425		257	SEG81	75	
	158	COM7		-1275	208	SEG32	-2375		258	SEG82	125	
	159	COM6		-1325	209	SEG33	-2325		259	SEG83	175	
	160	COM5		-1375	210	SEG34	-2275		260	SEG84	225	
.D	161	COM4		-1425	211	SEG35	-2225		261	SEG85	275	
	162	СОМЗ		-1475	212	SEG36	-2175		262	SEG86	325	
	163	COM2		-1525	213	SEG37	-2125		263	SEG87	375	
	164	COM1		-1575	214	SEG38	-2075		264	SEG88	425	
	165	COM0		-1625	215	SEG39	-2025		265	SEG89	475	
	166	NC	♦	-1675	216	SEG40	-1975		266	SEG90	525	
	167	NC	-4704	-1846	217	SEG41	-1925		267	SEG91	575	
	168	NC	-4621		218	SEG42	-1875		268	SEG92	625	
	169	NC	-4539		219	SEG43	-1825		269	SEG93	675	
	170	NC	-4456		220	SEG44	-1775		270	SEG94	725	
	171	NC	-4374		221	SEG45	-1725		271	SEG95	775	
	172	NC	-4291		222	SEG46	-1675		272	SEG96	825	
	173	NC	-4209		223	SEG47	-1625		273	SEG97	875	
	174	NC	-4126		224	SEG48	-1575		274	SEG98	925	
	175	NC	-4044 2075	1010	225	SEG49	-1525		275	SEG99	975	
	176 177	SEG0	-3975 -3925	-1818	226 227	SEG50	-1475 -1425		276 277	SEG100	1025	
	177	SEG1 SEG2	-3925 -3875		228	SEG51 SEG52	-1425 -1375		278	SEG101 SEG102	1075 1125	
	179	SEG3	-3825		229	SEG53	-1375 -1325		279	SEG102	1175	
	180	SEG4	-3775		230	SEG54	-1325 -1275		280	SEG104	1225	
	181	SEG5	-3725		231	SEG55	-1225		281	SEG105	1275	
	182	SEG6	-3675		232	SEG56	-1175		282	SEG106	1325	
	183	SEG7	-3625		233	SEG57	-1125		283	SEG107	1375	
	184	SEG8	-3575		234	SEG58	-1075		284	SEG108	1425	
	185	SEG9	-3525		235	SEG59	-1025		285	SEG109	1475	
	186	SEG10	-3475		236	SEG60	-975		286	SEG110	1525	
	187	SEG11	-3425		237	SEG61	-925		287	SEG111	1575	
	188	SEG12	-3375		238	SEG62	-875		288	SEG112	1625	
	189	SEG13	-3325		239	SEG63	-825		289	SEG113	1675	
	190	SEG14	-3275		240	SEG64	-775		290	SEG114	1725	
	191	SEG15	-3225		241	SEG65	-725		291	SEG115	1775	
	192	SEG16	-3175		242	SEG66	-675		292	SEG116	1825	
	193	SEG17	-3125		243	SEG67	-625		293	SEG117	1875	
	194	SEG18	-3075		244	SEG68	<i>–</i> 575		294	SEG118	1925	
	195	SEG19	-3025		245	SEG69	-525		295	SEG119	1975	
	196	SEG20	-2975		246	SEG70	-475		296	SEG120	2025	
	197	SEG21	-2925		247	SEG71	-425		297	SEG121	2075	
	198	SEG22	-2875		248	SEG72	-375		298	SEG122	2125	
	199	SEG23	-2825		249	SEG73	-325		299	SEG123	2175	
	200	SEG24	-2775	▼	250	SEG74	-275	▼	300	SEG124	2225	▼

Unit: µm

											חוו: μm
PAD No.	Pin Name	Х	Y	PAD No.	Pin Name	X	Y	PAD No.	Pin Name	X	Y
301	SEG125	2275	-1818	351	COM71	4958	-1375	401	COM121	4958	1125
302	SEG126	2325		352	COM72		-1325	402	COM122		1175
303	SEG127	2375		353	COM73		-1275	403	COM123		1225
304	SEG128	2425		354	COM74		-1225	404	COM124		1275
305	SEG129	2475		355	COM75		-1175	405	COM125		1325
306	SEG130	2525		356	COM76		-1125	406	COM126		1375
307	SEG131	2575		357	COM77		-1075	407	COM127		1425
308	SEG132	2625		358	COM78		-1025	408	COM128		1475
309	SEG133	2675		359	COM79		- 975	409	COM129		1525
310	SEG134	2725		360	COM80		-925	410	COM130		1575
311	SEG135	2775		361	COM81		-875	411	COM131		1625
312	SEG136	2825		362	COM82		-825	412	NC	*	1675
313	SEG137	2875		363	COM83		–775				
314	SEG138	2925		364	COM84		–725				
315	SEG139	2975		365	COM85		- 675				
316	SEG140	3025		366	COM86		-625				
317	SEG141	3075		367	COM87		<i>–</i> 575				
318	SEG142	3125		368	COM88		-525				
319	SEG143	3175		369	COM89		<i>–</i> 475				
320	SEG144	3225		370	COM90		– 425				
321	SEG145	3275		371	COM91		-375				
322	SEG146	3325		372	COM92		-325				
323	SEG147	3375		373	COM93		-275				
324	SEG148	3425		374	COM94		-225				
325	SEG149	3475		375	COM95		-175				
326	SEG150	3525		376	COM96		-125				
327	SEG151	3575		377	COM97		-75				
328	SEG152	3625		378	COM98		-25				
329	SEG153	3675		379	COM99		25				
330	SEG154	3725		380	COM100		75				
331	SEG155	3775		381	COM101		125				
332	SEG156	3825		382	COM102		175				
333	SEG157	3875		383	COM103		225				
334	SEG158	3925		384	COM104		275				
335	SEG159	3975	1040	385	COM105		325				
336	NC NC	4044	-1846	386	COM106		375				
337	NC NC	4126		387	COM107		425				
338	NC NC	4209		388	COM108		475				
339	NC NC	4291		389	COM109		525				
340	NC NC	4374		390	COM110		575				
341	NC NC	4456		391	COM111		625				
342	NC NC	4539		392	COM112		675				
343	NC NC	4621		393	COM113		725				
344	NC NC	4704	1675	394	COM114		775				
345	NC	4958	-1675	395	COM115		825				
346	COM66		-1625	396	COM116		875				
347	COM67		-1575	397	COM117		925				
348	COM68		-1525	398	COM118		975				
349	COM69		-1475	399	COM119		1025				
350	COM70	<u> </u>	-1425	400	COM120	▼	1075				

5. PIN DESCRIPTION

5.1 Power Pin

		pins
Power supply	Connect to system MPU power supply pin Vcc.	6
Power supply	Connect to the system GND. MV3 is short circuited with MV3 inside the IC chip.	8
Power supply	A liquid crystal drive multi-level power supply. The voltages determined by the liquid crystal cell are impedance-converted by resistive divider and operational amplifier for application. The following order must be maintained: $V_3 \ge V_2 \ge V_1 \ge V_2 \ge MV_1 \ge MV_2 \ge MV_3$ (=Vss) Master operation: When power supply is turned on, the following voltage is applied to each pin by the built-in power supply circuit. MV3 is connected to with Vss inside the IC chip. $ V_2 11/14 \bullet V_3 \\ V_1 9/14 \bullet V_3 \\ V_2 7/14 \bullet V_3 \\ V_3 V_4 5/14 \bullet V_3 $	14 (2 each)
P SI	ower upply ower	Connect to the system GND. MV3 is short circuited with Mv3 inside the IC chip. A liquid crystal drive multi-level power supply. The voltages determined by the liquid crystal cell are impedance-converted by resistive divider and operational amplifier for application. The following order must be maintained: V3 ≥ V2 ≥ V1 ≥ VC ≥ MV1 ≥ MV2 ≥ MV3 (=Vss) Master operation: When power supply is turned on, the following voltage is applied to each pin by the built-in power supply circuit. MV3 is connected to with Vss inside the IC chip. V2 11/14 • V3 V1 9/14 • V3

5.2 LCD Power Supply Circuit Pin

Pin name	I/O	Description	Number of pins			
CAP1+	0	Pin connected to the positive side of the step-up capacitor. Connect the capacitor between this pin and CAP1– pin.	2			
CAP1-	0	Pin connected to the negative side of the step-up capacitor. Connect the capacitor between this pin and CAP1+ pin.	2			
CAP2+	Connect the capacitor between this pin and CAP2– pin.					
CAP2-	0	Pin connected to the negative side of the step-up capacitor. Connect the capacitor between this pin and CAP2+ pin.	2			
Vout	0	Output pin for step-up. Connect the capacitor between this pin and VDD.	2			
CAP3+	0	Pin connected to the positive side of the step-up capacitor. Connect the capacitor between this pin and CAP3– pin.	2			
CAP3-	0	Pin connected to the negative side of the step-up capacitor. Connect the capacitor between this pin and CAP3+ pin.	2			
CAP4+	0	Pin connected to the positive side of the step-up capacitor. Connect the capacitor between this pin and CAP4– pin.	2			
CAP4-	0	Pin connected to the negative side of the step-up capacitor. Connect the capacitor between this pin and CAP4+ pin.	2			
CPP+	0	Keep it open.	1			
CPP-	0	Keep it open.	1			
CPM+	0	Keep it open.	1			
CPM-	0	Keep it open.	1			

5.3 System Bus Connection Pin

Pin name	I/O			Description	n		Number of pins		
D7 to D0 (SI) (SCL)	I/O	bi-direction When the serial data In this case	to the 8-bit or on all data bus. serial interface a input (SI) and se, D0 through Ct is inactive, D0	is selected (P D6 serves as D5 go to a high	/S = LOW), D7 the serial cloc impedance st	serves as the ck input (SCL), ate. When the	8		
A0	l	to disting	the least signifuish between dallGH: indicates that.OW: indicates	ata and comm at D0 to D7 are di	and. splay data or com	mand parameters.	1		
RES	I		hen the RES is LOW, initialization is achieved. esetting operation is done on the level of the RES signal.						
CS1 aCS2et4U.co	l m		chip select signal. When $\overline{\text{CS1}}$ = LOW and CS2 = HIGH, signals e active, and data/command input/output are enabled.						
RD (E)	I	A pin Wher is in t • When t	When the 80 series MPU is connected. A pin for connection of the RD signal of the 80 series MPU. When this signal is LOW, the data bus of the S1D15E06 series is in the output state. When the 68 series MPU is connected. Serves as a 68 series MPU enable clock input pin.						
WR (R/W)	I	A pin Signa WR s • Serves MPU is	When the 80 series MPU is connected. A pin for connection of the WR signal of the 80 series MPU. Signals on the data bus are latched at the leading edge of the WR signal. Serves as a read/write control signal input pin when the 68 series MPU is connected. R/W = HIGH: Read						
C86	I	C86 = H	terface switchir HIGH: 68 serie LOW: 80 serie	es MPU interfa			1		
P/S	I	Parallel d P/S = HIO P/S = LO	Parallel data input/serial data input select pin P/S = HIGH: Parallel data input P/S = LOW: Serial data input The following Table shows the summary:						
		P/S Da							
		HIGH	A0	D0 to D7	RD, WR				
		LOW	LOW A0 SI (D7) Write only SCL (D6)						
		When P/S <u>D0</u> to D5 RD(E) an The serial							

Pin name	1/0			Ι	Descrip	tion				Number of pins
CLS	I	circuit for CLS = CLS = When C the S1D	or displ = HIGH = LOW CLS is I 015E06	lay clock. ⊟: Built-in osc : Built-in osc _OW, display	cillator ci illator ci clock is ed in the	rcuit E rcuit D input f	nabled isabled (rom the	ilt-in oscillator External input) CL pin. When node, each CL		1
			Dis	play clock		Ма	ster	Slave		
		Built		cillator circuit	used		GH	HIGH		
			Ext	ernal input		LC	DW	LOW		
M/S ww.DataSheet4U.co	I	Liquid c operation display, for liquid M/S = M/S =	rystal on outp while d crysta HIGH LOW	display systen uts the timing the slave ope al display. : Master ope : Slave opera	n is synd I signal I ration in eration ation	chroniz equire puts th	ed when d for liqu ne timing		k	1
		M/S	CLS	Oscillation circuit	Pow	_	CL	FR, DOF , F1, F2, CA		
			HIGH LOW	Enabled Disabled	Enak Enak	led	Output Input	Output Output		
			HIGH LOW	Disabled Disabled	Disal Disal		Input Input	Input Input		
		The slav	ve pow	er supply circ	uit can a	also op	erate, b	ut do not use it		
CL	I/O			nput/output p ole shows the re		onforma	ance to the	M/S and CLS sta	ıte:	1
		ПСП	CLS HIGH LOW	CL Output Input						
			HIGH LOW	Input Input						
				nt to use the S t each CL pin		06 seri	es in the	e master/slave		
FR	I/O	M/S = M/S = When y	: HIGH : LOW ou war	I alternating c : Output : Input nt to use the S t each FR pin	S1D15E(master/slave		1
F1, F2, CA	I/O	M/S = M/S = When y	: HIGH : LOW ou war	I sync signal i : Output : Input nt to use the S t each F1, F2	S1D15E()6 seri		master/slave		3 (1 each)
DOF	I/O	A liquid M/S = M/S = When y	crysta : HIGH : LOW ou war	l blanking con :Output :Input	itrol pin. S1D15E		es in the	master/slave		1

5.4 Liquid crystal drive pin

Pin name	name I/O Description						
SEG0 to SEG159	0	Liquid crystal segment drive output pins. One of the V2, V1, Vc, MV1, and MV2 levels is selected by a combination of the display RAM content and FR/F1/F2 signals.	160				
COM0 to COM131	0	Liquid crystal common drive output pins. One of the V ₃ , V _C , MV ₃ (Vss) levels is selected by a combination of the scan data and FR/F1/F2 signals.	132				

5.5 Test pins

	Pin name	I/O	Description	Number of pins
	TEST,	1	IC chip test pins. Lock them to LOW.	5
.D	aTEST24to.5	n		
	TEST0, 1, 6 to 18	I/O	IC chip test pins. Open them and make sure that the capacity is not consumed by wiring, etc.	15

6. FUNCTIONAL DESCRIPTION

6.1 MPU Interface

6.1.1 Selection of Interface Type

S1D15E06 series allows data to be sent via the 8-bit bi-directional data buses (D7 to D0) or serial data input (SI). By setting the polarity of the P/S pin to HIGH or LOW, you can select either 8-bit parallel data input or serial data input, as shown in Table 6.1.

Table 6.1

P/S	CS1	CS2	A0	RD	WR	C86	D7	D6	D5 to D0
HIGH: Parallel input	CS1	CS2	A0	RD	WR	C86	D7	D6	D5 to D0
LOW : Serial input	CS1	CS2	Α0	_	_	_	SI	SCL	(HZ)

—: Fixed to HIGH or LOW HZ: High impedance state

6.1.2 parallel interface

When the parallel interface is selected (P/S = HIGH), direction connection to the MPU bus of either 80 series MPU or www.D68 series MPU is performed by setting the 86 pin to either HIGH or LOW, as shown in Table 6.2.

Table 6.2

P/S	CS1	CS2	A0	RD	WR	D7 to D0
HIGH: 68 series MPU bus	CS1	CS2	A0	Е	R/W	D7 to D0
LOW: 80 series MPU bus	CS1	CS2	A0	RD	WR	D7 to D0

The data bus signals are identified by a combination of A0, \overline{RD} (E), and \overline{WR} (R/W) signals as shown in Table 6.3.

Table 6.3

Common	mon 68 series 80 series		eries	Formation
Α0	R/W	RD	WR	Function
1	1	0	1	Display data read, status read
1	0	1	0	Display data write, command parameter write
0	1	1	0	Command write

6.1.3 Serial interface

When the serial interface is selected (P/S =LOW), the chip is active $\overline{(CS1}$ = LOW, CS2 = HIGH), and reception of serial data input (SI) and serial clock input (SCL) is enabled. Serial interface comprises a 8-bit shift register and 3-bit counter. The serial data are latched by the rising edge of serial clock signals in the order of D7, D6, and D0 starting from the serial data input pin. On the rising edge of 8th serial clock signal, they are converted into 8-bit parallel data to be processed.

Whether serial data input is a display data or command is identified by A0 input. A0 = HIGH indicates display data, while A0 = LOW shows command data. The A0 input is read and identified at every $8 \times n$ -th rising edge of the serial clock after the chip has turned active.

Fig. 6.1 shows the serial interface signal chart.

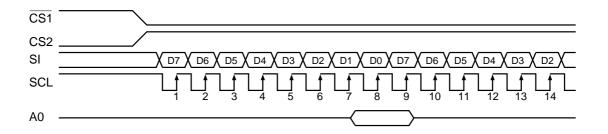


Fig. 6.1

- * When the chip is inactive, the counter is reset to the initials state.
- * Reading is not performed in the case of serial interface.
- * For the SCL signal, a sufficient care must be taken against terminal reflection of the wiring and external noise. Recommend to use an actual equipment to verify the operation.

6.1.4 Chip Selection

The S1D15E06 series has two chip select pins; $\overline{CS1}$ and CS2. MPU interface or serial interface is enabled only when $\overline{CS1} = LOW$ and CS2 = HIGH.

When the chip select pin is inactive, $\underline{D0}$ to $\underline{D5}$ are in the state of high impedance, while A0, \overline{RD} and \overline{WR} inputs are disabled. When serial interface is selected, the shift register and counter are reset.

6.1.5 Access to display data RAM and internal register

Access to S1D15E06 series viewed from the MPU side is enabled only if the cycle time requirements are kept. This does not required waiting time; hence, high-speed data transfer is allowed.

Furthermore, at the time of data transfer with the MPU, S1D15E06 series provides a kind of inter-LSI pipe line

processing via the bus holder accompanying the internal data bus.

For example, when data is written to the display data RAM by the MPU, the data is once held by the bus holder. It is written to the display data RAM before the next data write cycle comes.

On the other hand, when the MPU reads the content of the display data RAM, it is read in the first data read cycle (dummy), and the data is held in the bus holder. Then it is read onto on the system bus from the bus holder in the next data read cycle. Restrictions are imposed on the display data RAM read sequence. When the address has been set, specified address data is not output to the Read command immediately after that. The specified address data is output in the second data reading. This must be carefully noted. Therefore, one dummy read operation is mandatory subsequent to address setting or write cycle. Fig. 6.2 illustrates this relationship.

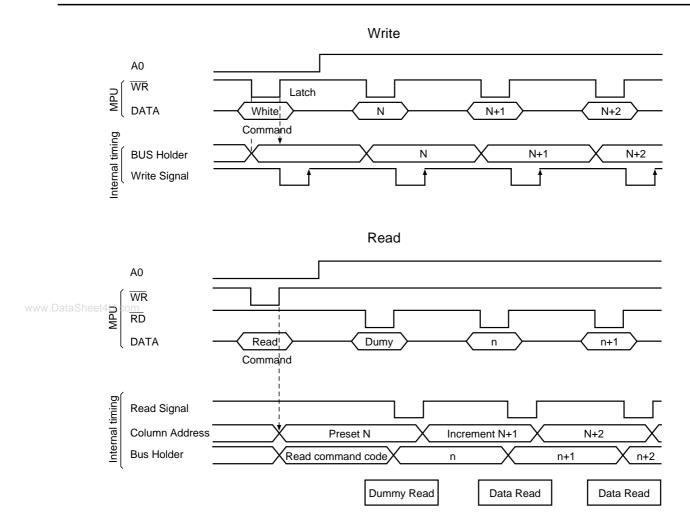


Fig. 6.2

6.2 Display data RAM

6.2.1 Display Data RAM

This is a RAM to store the display dot data, and comprises $132 \times 160 \times 2$ bits. Access to the desired bit is enabled by specifying the page address and column address. When the 4 gray-scale is selected by the Display Mode command, display data input for gray-scale display are processed as a two-bit pair. Combination is as follows:

$$(MSB, LSB) = (D1,D0), (D3,D2), (DS,D4), (D7,D6)$$

When the RAM bit data is gray-scale 1 and 2, gray-scale display is realized according to the parameter of the Gray-scale Pattern Set command.

RAM bit data (high order and low order)

(1,1): gray-scale 3 Black (when display is in normal mode)

(1,0): gray-scale 2 (0,1): gray-scale 1

(0,0): gray-scale 0 White (when display is in

normal mode)

When binary display is selected by the Display Mode command, the RAM 1 bit built in the one-dot pixel responds to it. When the RAM bit data is "1", the display is black. If it is "0", the display is given in white.

RAM bit data

"1": Light On Black (when display is in

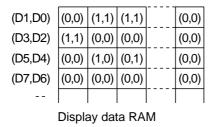
normal mode)

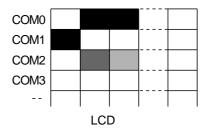
"0": Light Off White (when display is in

normal mode)

Display data D7 to D0 from the MPU correspond to LCD common direction, as shown in Fig. 6.3 and 6.4. Therefore, less restrictions when multi-chip usage. Furthermore, read/write operations from the MPU to the RAM are carried out via the input/output buffer.

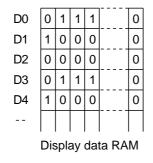
The read operation from Display data RAM is designed as an independent operation. Accordingly, even if the MPU accesses the RAM asynchronously during LCD display, no adverse effect is given to display.





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Fig. 6.3 4 gray-scale



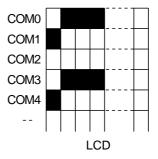


Fig. 6.4 Binary

6.2.2 Gray-scale display

When the 4 gray-scale is selected by the Display Mode command, gray-scale is represented by the FRM control carried out according to the gray-scale data written in the display data RAM.

Of the 4 gray-scale, 2 gray-scale of halftones (gray-scale 2 and 1) has its level of contrast specified by the Gray-scale Set command. Gray-scale can be selected from 6 levels of contrast.

6.2.3 Page address circuit/column address circuit

The address of the display data RAM to be accessed is specified by the Page Address Set command and Column Address Set command, as shown in Fig. 6.5 and Fig. 6.6. For Address incremental direction, either the column direction or page direction can be selected by the Address Direction command. Whichever direction is chosen, increment is carried out by positive one (+1) after write

or read operation.

When the column direction is selected for address increment, the column address is increased by +1 for every write or read operation. After the column address has accessed up to 9FH, the page address is incremented by +1 and the column address shifts to 0H.

When the page direction is selected for address increment, the page address is increased with the column address locked in position. When the page address has accessed up to 32H, the column address is incremented by +1, and the page address goes to 0H.

Whichever direction is selected for address increment, the page address goes back to 0H and the column address to 0H after access up to the column address 9FH of page address 32H.

As shown in Fig. 6.4, relationship between the display data RAM column address and segment output can be reversed by the Column Address Set Direction command. This will reduce restrictions on IC layout during LCD module assembling.

Table 6.4

SEG o	utput	SEG0		SEG159
ADC	"0"	0(H)→	Column Address	→9F(H)
(D0)	"1"	9F(H)←	Column Address	←0(H)

6.2.4 Line address circuit

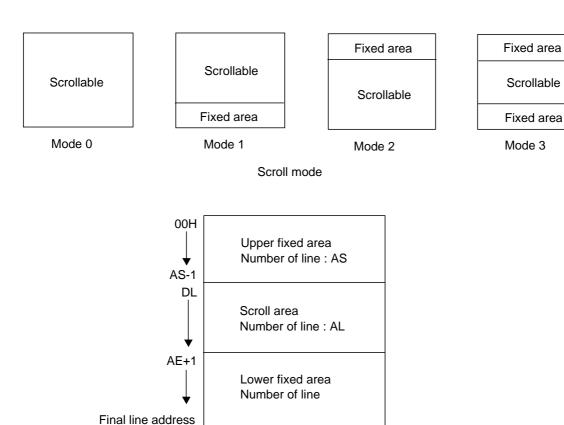
The line address circuit specifies the line address corresponding to COM output when the contents of the display data RAM is displayed, as shown in Fig. 6.5 and 6.6. Normally, the top line of the display (COM0 output in the case of normal rotation of the common output status and COM131 output in the case of reverse rotation) is specified by the Display Start Line Address Set command. The display area starts from the specified display start line address to cover the area corresponding to the lines specified by the DUTY Set command in the direction where the line address increments.

If the display start line address set command is used for

dynamic modification of the line address, screen scroll and page change are enabled.

6.2.5 Area scroll

The display area can be divided into the display area fixed in the COM direction and scrollable area by the area scroll command. The scroll area is set by a scroll mode, scroll start line address (AS), scroll end address (AE), and scroll display line count (AL) as parameters for the area scroll command. Display start line address (DL) in the scroll area can be specified by the display start line address set command.



6.2.5.1 Mode 0 (full screen scroll)

This mode releases the area scroll. Parameters AS, AE and AL are disabled,

6.2.5.2 Mode 1 (Upper scroll)

Reading starts from the line address DL to read AL lines as a scroll area. If the line address AE is read in the

middle of reading the scroll area, the line address to be read next will be 00H. When all the AL lines have been read, the address to be read next will be AE+1. When reading is completed up to the final line address, the control goes back to the line address DL, and parameter AS is disabled. DL can be specified in the range from 00H to AE.

6.2.5.3 Mode 2 (lower scroll)

Reading starts from line address 00H to reach the line address AS-1 in the continuous reading mode. Upon completion of reading of line address AS-1, the line address moves to the DL to read the area corresponding to AL lines from the line address DL as a scroll area. If the final line address is read in the middle of reading the scroll area, the line address to be read next will be AS. When all AL lines have been read, the control goes back to the line address 00H, and parameter AE is disabled. DL can be specified in the range from AS to the final line address.

6.2.5.4 Mode 3 (Center scroll)

Reading starts from line address 00H to reach the line address AS-1 in the continuous reading mode.

Upon completion of reading of line address AS-1, the www.Dine address moves to the DL to read the area corresponding to AL lines from the line address DL as a scroll area. If the final line address is read in the middle of reading the scroll area, the line address to be read next will be AS. When all AL lines have been read, the line address will be AE+1. When up to the final line address has been read, the control goes back to the line address 00H, DL can be specified in the range from AS to AE.

6.2.6 Display data latch circuit

The display data latch circuit is a latch to temporarily latch the display data output from then display data RAM to the liquid crystal drive circuit. Display normal/reverse, display ON/OFF, and display all lighting ON/OFF commands control the data in this latch, without the data in the display data RAM being controlled.

6.2.7 Partial display

Partial display of the screen is provided by the partial display ON/OFF command. The partial area (display start line, number of display lines) are set by the partial display set command.

The display start line of the parameter shows the line assigned in the COM direction of the liquid crystal screen. It is different from the line address given in Fig. 6.5 and 6.6.

Example: When the point is set at 1 (COM4 to 7) by the Duty Reset command, the display line is assigned as shown below. If the display start line 4 and display line count 3 are specified by the partial display set command, the display area is COM8 to COM10.

Display line	LCD panel	
0		COM4
1		COM5
2		COM6
3		COM7
4		COM8
5		COM9
6		COM10
7		COM11
8		COM12
9		COM13
10		COM14
1		

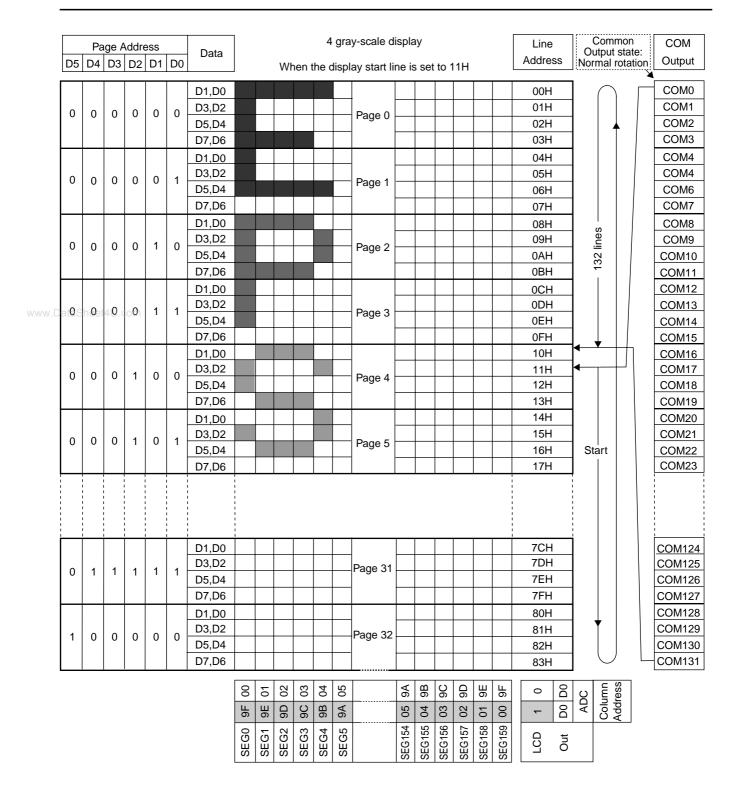


Fig. 6.5 4 gray-scale

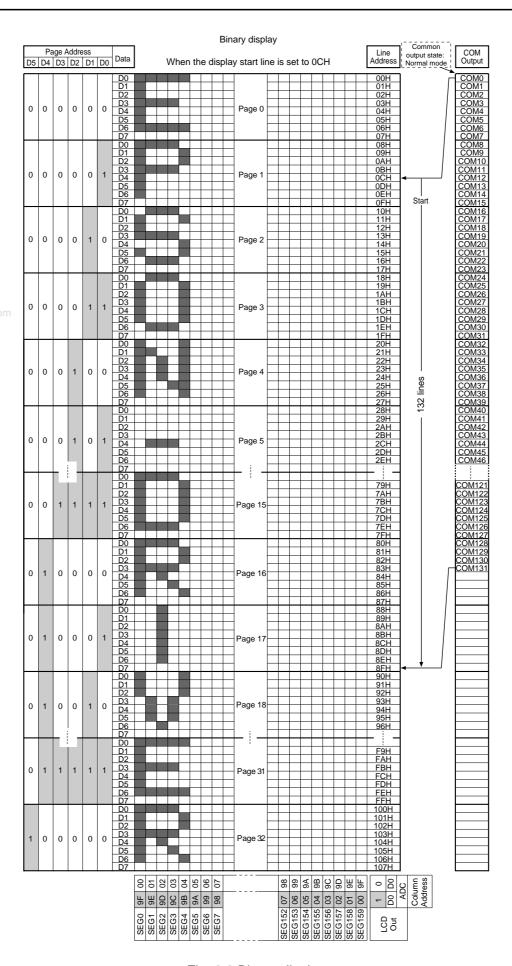


Fig. 6.6 Binary display

6.3 Oscillator circuit

A display clock is generated by the CR oscillator. The oscillator circuit is enabled only when M/S = HIGH and CLS = HIGH. Oscillation starts after input of the built-in oscillator circuit ON command input.

When CLS = LOW, oscillation stops, and display clock is input from the CL pin.

6.4 Display timing generation circuit

Timing signals are generated from the display clock to the line address circuit and display data latch circuit. Synchronized with display clock, display data is latched in display data latch circuit, and is output to the segment drive output pin. Reading of the display data into the LCD drive circuit is completely independent of access from the MPU to the display data RAM. Accordingly, asynchronous access to the display data RAM during

flicker.

Furthermore, the display clock generates internal common timing, liquid crystal alternating signal(FR), field start signal (CA) and drive pattern signal (Fl and F2).

The FR normally generates 2-frame alternating drive system drive waveform to the liquid crystal drive circuit. The n-line reverse alternating drive waveform is generated for each $4 \times (a+1)$ line by setting data on the n-line reverse drive register. When there is a display quality problem including crosstalk, the problem may be solved using the n-line reverse alternating drive. Execute liquid crystal display to determine the number

Execute liquid crystal display to determine the number of lines "n" for alternation.

When you want to use the S1D15E06 series in multichip configuration, supply display timing signal (FR, CA, F1, F2, CL, DOF) to the slave side from the master side. Table 6.5 shows the statuses of FR, CA, F1, F2, CL, DOF.

Table 6.5

Operating mode	CL	FR, CA, F1, F2, DOF
Master (M/S = HIGH) Built-in oscillator circuit enabled (CLS = HIGH	Output	Output
Built-in oscillator circuit disabled (CLS = LOW	Input	Output
Slave (M/S = LOW) Built-in oscillator circuit enabled (CLS = HIGH	Input	Input
Built-in oscillator circuit disabled (CLS = LOW	Input	Input

6.5 Liquid crystal drive circuit

6.5.1 SEG Drivers

This is a SEG output circuit. It selects the five values of V2, V1, VC, MV1 and MV2 using the driver control signal determined by the decoder, and output them.

6.5.2 COM Drivers

This is a COM output circuit. It selects three values of V3, Vc and MV3(VSS) using the driver control signal determined by the decoder, and output them.

S1D15E06 series allows the COM output scanning direction to be set by the common output status select command. (See Table 6.6). This will reduce restrictions on IC layout during LCD module assembling.

Table 6.6

Status	Direction	of COM	scanning
Normal	COM 0	\rightarrow	COM 131
Reverse	COM 131	\rightarrow	COM 0

6.6 Power supply circuit

This is a power supply circuit to generate voltage required for liquid crystal drive, and is characterized by a low power consumption. It consists of a step-up circuit, voltage regulating circuit and liquid crystal drive voltage generating circuit, and is enabled only during master operation. The power supply circuit uses the power control set command to provide an on/off

control of step-up circuit, voltage regulating circuit and liquid crystal drive potential generating circuit. This allows a combined use of the external power supply and part of built-in power supply functions. Table 6.7 shows functions controlled by the 5-bit data of the control set command, and Table 6.8 shows reference combinations. The power supply circuit is enabled only during master operation.

Table 6.7 Control by 5-bit data of the control set command

Item	Sta	ate	Triple	Double	Single
	"1"	"0"			
D4 Step-cut circuit scaling factor select bit 1	ı	ı	1	1	0
D3 Step-cut circuit scaling factor select bit 2	-	-	1	0	1
D2 Step-cut circuit control bit	ON	OFF	_	_	_
D1 Voltage regulator circuit (Vc regulator circuit) control bit	ON	OFF	_	_	_
D0 LCD driving potential generating circuit (LCDV circuit) control bit	ON	OFF	_	_	_

Table 6.8 Reference combination

Circuits used	D4	D3	D2	D1	D0	Step-up circuit	Vc regulator circuit	LCDV circuit	Eternal input power supply
① Use of all built-in power supplies									
Triple step-up	1	1	1	1	1	○ "1"	○ "1"	○ "1"	_
Double step-up	1	0	1	1	1	○ "1"	○ "1"	○ "1"	_
Vout = Vdd	0	1	1	1	1	○ "1"	O "1"	○ "1"	_
② Vc regulating circuit and LCDV circuit only	0	0	0	1	1	× "0"	O "1"	○ "1"	Vout
③ LCDV circuit only	0	0	0	0	1	× "0"	× "0"	○ "1"	Vc
④ External power supply only (S1D15E06D00B*)	0	0	0	0	0	× "0"	× "0"	× "0"	V3, V2, V1, VC, MV1, MV2

^{*} Any combinations other than the above are not available.

^{*100}ms or more should be kept from Vc regulator circuit ON to LCDV circuit ON.

6.6.1 Step-up circuit

VDD-Vss potential can be triple and double step-up by the step-up circuit built in the S1D15E06 series. The status of Vout = Vdd can be selected by stopping the operation of the triple and double step-up circuit using the command

① When used by switching between the triple, double step-up and VOUT = VDD using a command:

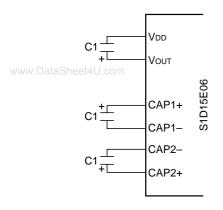
Capacitors C1 are connected between CAP1+ <-> CAP1, between CAP2+ <-> CAP2 and between VDD <-> VOUT for use.

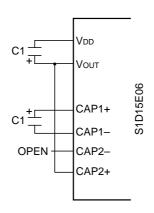
② When used by switching between the double step-up and Vout = VDD using a command:

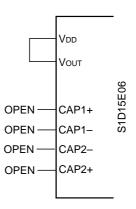
Capacitors C1 are connected between CAP1+ <-> CAP1 and between VDD <-> VOUT for use.

 \bigcirc Only VouT = VDD is used.

VDD pin and VOUT pin are connected for use.

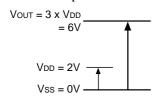


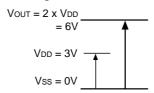


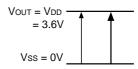


- ① Triple, double step-up or $V_{OUT} = V_{DD}$
- ② Double step-up or VOUT = VDD
- ③ VOUT = VDD (without step-up)

Fig.6.7 shows the potential relationship for boosting.







Triple step-up potential relationship

Double step-up potential relationship

Vout = VDD potential relationship

Fig. 6.7

^{*} Set the VDD voltage range so that the VOUT pin voltage does not exceed the absolute maximum rating.

6.6.2 Voltage Regulating Circuit

Vout generated from the step-up circuit or Vout input from the outside produces liquid crystal drive voltage VC via the voltage regulating circuit. The voltage regulating circuit is controlled by liquid crystal drive voltage change command and electronic volume.

The S1D15E06 series has a high precision constant voltage source, and incorporates 4-step liquid crystal drive voltage change command and 128-step electronic volume functions. This makes it possible to provide a high precision liquid crystal drive voltage regulation

only by the command without adding any external parts. The variable range of the VC voltage is from about 1.6 to 7.0 [V]. When the internal step-up is used, or VOUT is input for use, the VOUT potential should be, in principle, the voltage 20% or more higher than the maximum voltage of the VC to be used, giving consideration to temperature characteristics.

Example: When VC output is 7 [V], VOUT \geq 8.4 [V] (three times 2.8 [V], etc.)

When VC output is 4 [V], VOUT \geq 4.8 [V] (two times 2.4 [V], three times 1.8 [V])

• Electronic volume

α of Table 6.9 indicates an electronic volume command value. It takes one of 128 states when the data is set in the 7-bit electronic volume register.

Table 6.9 shows the value of α by setting the data in the electronic volume register.

Table 6.9

D6	D5	D4	D3	D2	D1	D0	α	Voltage Vc
0	0	0	0	0	0	0	0	Small
0	0	0	0	0	0	1	1	↑
0	0	0	0	0	1	0	2	
1	1	1	1	1	0	1	125	
1	1	1	1	1	1	0	126	\downarrow
1	1	1	1	1	1	1	127	Large

• Liquid crystal drive voltage selection

The liquid drive voltage range can be selected from 3 states by the liquid crystal drive voltage select command using the two-bit crystal drive voltage select command register.

Table 6.10

D1	D0	Vc voltage output range
0	0	1.77V to 3.50V
1	0	2.53V to 5.00V
1	1	3.54V to 7.00V

Equation A-1 represents Vc logical values. For the output voltage of Vc, a manufacturing dispersion of up to \pm 3% should be taken into account.

Equation A-1

Unit [V]

Electronic	LCD voltage selection										
V R	D1	D1 D0		D1 D0		D0					
α	0	0	1	0	1	1					
	Vc (Max.) = 3.50V	Vc (Max.) = 5.00V	Vc (Max.) = 7.00V						
0 to 31	1.77 + 0.	$0195 \times \alpha$	2.53 + 0	$.028 \times \alpha$	$3.54 + 0.039 \times \alpha$						
32 to 63	2.39 + 0.01	$2.39 + 0.0156 \times (\alpha - 32)$ $3.42 + 0.0223 \times (\alpha - 32)$			4.78 + 0.03	$13 \times (\alpha - 32)$					
64 to 95	2.89 + 0.01	17 × (α–64)	4.12 + 0.01	67 × (α–64)	$5.77 + 0.0234 \times (\alpha - 64)$						
96 to 127	3.26 + 0.00	$78 \times (\alpha - 96)$	4.65 + 0.01	12 × (α–96)	6.52 + 0.01	$56 \times (\alpha - 96)$					

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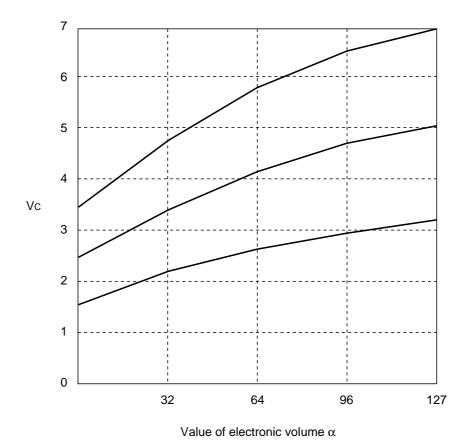


Figure 6.8

6.6.3 Liquid crystal drive voltage generation circuit

Voltage VC is boosting in the IC to generate potential V3. Furthermore, voltages V3 and VC are converted by resistive divider to produce V2, V1, MV1 and MV2 voltages. V2, V2, MV1 and MV2 voltages are impedance-converted by the voltage follower, and is supplied to the liquid crystal drive circuit.

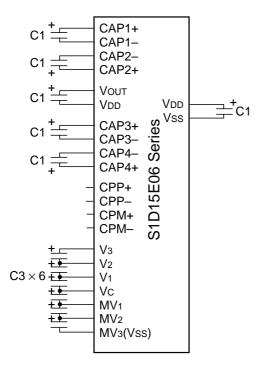
V2	11/14 • V3
V1	9/14 • V3
Vc	7/14 • V3
MV1	5/14 • V₃
MV2	3/14 • V3

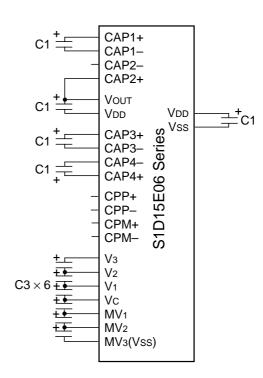
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An example of circuit around the power supply circuit ① Use of all built-in power supplies

When used by switching between the triple, double boosting and Vout = VDD: (12 C's)

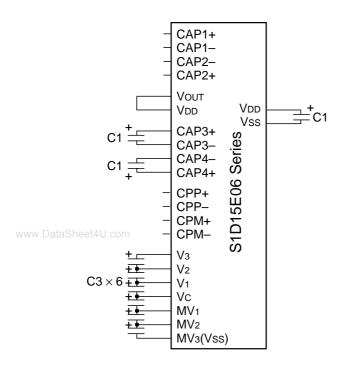
When used by switching between the double boosting and VOUT = VDD: (11 C's)

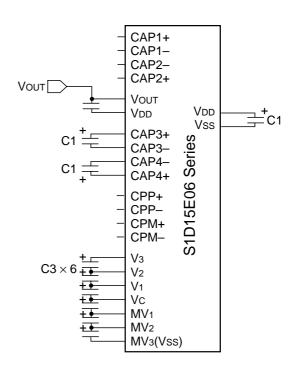




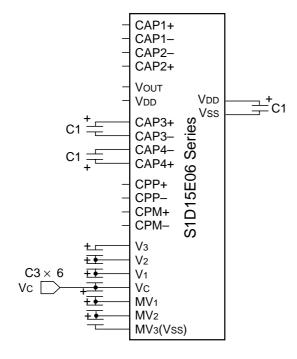
Only VOUT = VDD is used: (9 C's)

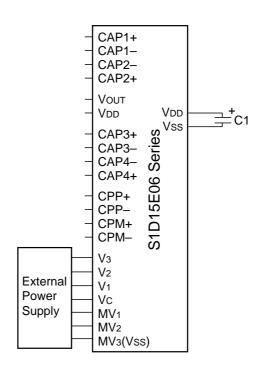
② VC regulating circuit and LCDV circuit VOUT external input (10 C's)





③LCDV circuit only Vc external input (9 C's) External power supply only external input (1 C)





Examples of common reference settings

Item	Settings	Unit
C1	1.0 to 4.7	μF
C2	0.47 to 1.0	
C3	0.47 to 1.0	

*5 Precautions when installing the COG

When installing the COG, it is necessary to duly consider the fact that there exists a resistance of the ITO wiring occurring between the driver chip and the externally connected parts (such as capacitors and resistors). By the influence of this resistance, non-conformity may occur with the indications on the liquid crystal display. When installing the COG, we recommend to use the "④ External power supply only"

6.6.4 Temperature gradient select circuit

This is a circuit to select the temperature gradient characteristics of the liquid crystal drive power supply voltage. Temperature gradient characteristics can be selected from eight states by the Temperature Gradient command. Selection of temperature gradient characteristics conforming to the temperature characteristics of the liquid crystal to be used makes it possible to configure a system without providing an external element for temperature characteristics compensation.

6.7 Reset circuit

When the RES input becomes LOW, this LSI is set to the initialized state.

The following shows the initially set state:

1. Display: OFF

2. Display OFF mode: Vss output

3. Display: normal mode

4. Display all lighting: OFF

5. Common output status : normal

6. Display start line: Set to 1st line

7. Page address: Set to 0 page

8. Column address: Set to 0 address

9. Display data input direction : Column direction

10. Column address direction: forward

11. n-line a.c. reverse drive : OFF (reverse drive for each frame)

12. n-line reverse drive register : (D4, D3, D2, D1, D0) = (0, 1, 1, 0, 0)

13. Display mode : 4 gray-scale display

14. Gray-scale pattern register : (D7, D6, D5, D4, D3, D2, D1, D0) = (*, 1, 0, 1, *, 0, 1, 0)

15. Area scroll:

Scroll mode : (D1, D0) = (0, 0)

 $Scroll\ start\ address: (D7, D6, D5, D4, D3, D2, D1,$

D0) = (0, 0, 0, 0, 0, 0, 0, 0)

Scroll terminating address: (D7, D6, D5, D4, D3,

D2, D1, D0) = (0, 0, 0, 0, 0, 0, 0, 0)

Number of display lines: (D7, D6, D5, D4, D3, D2,

D1, D0) = (0, 0, 0, 0, 0, 0, 0, 0)

The optimum values for above-mentioned Cl, C2 and C3 vary according to the LCD panel to drive. Use the above-mentioned values as references. Actually verify the display of a pattern with big load to make a decision.

- 16. DUTY register: (D5, D4, D3, D2, D1, D0) = (1, 0, 0, 0, 0, 0) (1/132 duty) Start spot (block) register: (D5, D4, D3, D2, D1, D0) = (0, 0, 0, 0, 0) (COM0)
- 17. Partial display: OFF
- 18. Partial display start line: (D7, D6, D5, D4, D3, D2, D1, D0) = (0, 0, 0, 0, 0, 0, 0)

 Number of partial display lines: (D7, D6, D5, D4, D3, D2, D1, D0) = (0, 0, 0, 0, 0, 0, 0)
- 19. Read modify write: OFF
- 20. Built-in oscillation circuit: stop
- 21. Oscillation frequency register : (D3, D2, D1,D0) = (0, 0, 0, 0) (120 kHz)
- 22. Power control register : (D4, D3, D2, D1, D0) = (0, 0, 0, 0, 0)
- 23. Clock frequency for step-up/step-down Step-up: (D2, D1, D0) = (1, 0, 1) Step-down: (D6, D5, D4) = (1, 0, 1)
- 24. Liquid crystal drive voltage selection register : (D1,D0) = (0,0)
- 25. Electronic volume register : (D6, D5, D4, D3, D2, D1, D0) = (0, 0, 0, 0, 0, 0, 0)
- 26. Discharge : ON (only for when RES = LOW)
- 27. Power save: OFF
- 28. Temperature gradient resistor : (D2, D1, D0) = (0, 0, 0) (-0.06/°C)
- 29. Register data in the serial interface: Clear

When the Reset command is used, only the abovementioned inilialized items 7, 8 and 19 are executed.

When power is turned on, initialization by the \overline{RES} pin is necessary. After initialization by the \overline{RES} pin, each input pin must be controlled correctly.

Furthermore, when control signals from the MPU have a high impedance, the excessive current may flow to the IC.

After VDD is applied, measures should be taken to ensure that the input pin does not have a high impedance. The S1D15E06 series discharges the electric charge of VOUT and liquid crystal drive voltage (V3, V2, V1, VC, MV1, MV2) at the level of RES pin = LOW. When liquid crystal drive external power supply is used, external power supply should not be supplied during the period of RES = LOW to prevent external power supply and VDD from being short circuited.

7. COMMAND

The S1D15E06 series identifies data bus signals by a combination of A0, $\overline{RD}(E)$ and $\overline{WR}(R/\overline{W})$. Interpretation and execution of the command are executed by the internal timing alone which is independent of the external clock. This allows high-speed processing.

The 80 series MPU interface allows the command to be started by entering the low pulse in the \overline{RD} pin during reading and by entering the low pulse in the \overline{WR} pin during writing.

The 68 series MPU interface allows a read state to occur by entering HIGH in the $R\overline{/W}$ pin, and permits a write state to occur by entering LOW. It also allows the command to be started by entering the high pulse in the pin E. (For timing, see the description of "10. Timing characteristics").

Accordingly, the 68 series MPU interface is different from 80 series MPU interface in that $\overline{RD}(E)$ is "1(H)" in the case of display data/read shown in the Command Description and Command Table. The following describes the commands, based on the example of the 80 series MPU interface:

When the serial interface is selected, enter data sequentially starting from D7.

Command Description

(1) Display ON/OFF

This command sets the display ON/OFF.

When display OFF is specified, segment and common drivers outputs the level selected by the display OFF Mode Select command.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Output level
0	1	0	1	0	1	0	1	1	1	0 1	Display OFF Display ON

(2) Display OFF Mode Select

This command is used to set the output level of the segment and common driver when the display is off. In the initial setting state, it becomes "D0 = 0".

* When D0 = 0 is selected in the case of S1D15E06D00B*, the MV2 and common driver Vss level is output by segment driver when display is off. Select D0 = 1 to use the S1D15E06D00B*.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Output level
0	1	0	1	0	1	1	1	1	1	0	Vss Vc

(3) Display Normal/Reverse

This command allows the display ON/OFF state to be reversed, without having to rewrite the contents of the display data RAM. In this case, contents of the display data RAM are maintained.

	Е	R/W									
A0	RD	WR	D7	D6	D5	D4	D3	D2	D1	D0	Setting
0	1	0	1	0	1	0	0	1	1	0	RAM data = HIGH LCD ON Voltage (normal)
										1	RAM data = LOW LCD ON Voltage (reverse)

(4) Display All Lighting ON/OFF

This command forces all the displays to be turned on independently of the contents of the display data RAM. In this case, the contents of the display data RAM are maintained. Fully white display can also be made by a combination of the Display Reverse command.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Setting
0	1	0	1	0	1	0	0	1	0	0	Normal display status
										1	Display all lighting

(5) Common Output Status Select

This command allows the scanning direction of the COM output pin to be selected. For details, see the description of "6.5.2 COM Drivers" in the Function Description.

Dat	A0 ee	E t4U RD m	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	•	Selected state
	0	1	0	1	1	0	0	0	1	0	0	Normal	COM0 → COM131
											1	Reverse	COM131 \rightarrow COM0

(6) Display Start Line set (Parameter: 1 byte (4 gray-scale) and 2 bytes (binary))

The parameter following this command specifies the display start line address of the display data RAM shown in Fig. 6.5 and 6.6. When the Display Mode command is used to select 4 gray-scale display, a 1-byte parameter must be entered. When the binary display is selected, a 2-byte parameter must be entered.

The display area is indicated in the direction where line address numbers are incremented, starting from the specified line address. If a dynamic change of the line address is made by this command, smooth scrolling in the longitudinal direction and page breaking are enabled. For details, see the description of "6.2.4 Line address circuit" in the Function Description.

	E	R/W	D.7	D 0	D.E.	D 4	D 0	Б0	D4	D 0
A0	RD	WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	1	0	0	0	1	0	1	0
1	1	0	P7	P6	P5	P4	P3	P2	P1	P0
1	1	0	*	*	*	*	*	*	*	P8

Mode setting Register setting 1 Register setting 2

(only binary display required)

*: denote invalid bits.

• Display Start Line Set command parameter

(i) When the display mode is a 4 gray-scale mode:

The one-byte parameter is used to specify the address.

P7	P6	P5	P4	P3	P2	P1	P0	Line address
0	0	0	0	0	0	0	0	00H
0	0	0	0	0	0	0	1	01H
0	0	0	0	0	0	1	0	02H
				l				\downarrow
1	0	0	0	0	0	1	0	82H
1	0	0	0	0	0	1	1	83H

Set to the line address 00H at the time of resetting.

(ii) When the display mode is binary:

To specify the address, continuous 2-byte data is necessary. The first byte D0 is LSB, and the second byte D0 is MLB.

	P7	P6	P5	P4	P3	P2	P1	P0 P8	Line address
1st byte 2nd byte	0	0	0	0	0	0	0	0 0	00H
	0	0	0	0	0	0	0	1 0	01H
	0	0	0	0	0	0	1 *	0 0	02H
					,				\downarrow
	0	0	0	0	0	1 *	1 *	0 1	106H
	0 *	0	0	0	0	1 *	1 *	1 1	107H

Set to line address 000H at the time of resetting. *: denote invalid bits.

• Line address setting sequence

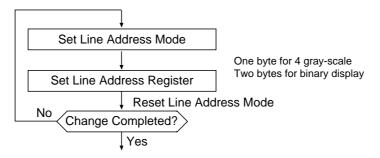


Fig. 7.1

(7) Page Address Set

This command specifies the page address corresponding to row address when MPU access to the display data RAM shown in Fig. 6.5 and 6.6. For details, see the description of "6.2.2 Page address circuit" in the Function Description.

	Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Page address
	0	1	0	1	0	1	1	0	0	0	1	Command
Ī	1	1	0	*	*	P5	P4	P3	P2	P1	P0	Page address setting

*: denote invalid bits.

P5	P4	P3	P2	P1	P0	Page address
0	0	0	0	0	0	0
0	0	0	0	0	1	1
		,	l			\downarrow
0	1	1	1	1	1	31
1	0	0	0	0	0	32

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(8) Column Address Set

This command sets the display data RAM column address given in Fig. 6.5 and 6.6. For details, see the description of "6.2.3 Column address circuit" in the Function Description.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	0	0	0	1	0	0	1	1
1	1	0	P7	P6	P5	P4	P3	P2	P1	P0

P 7	P6	P5	P4	P3	P2	P1	P0	Column address
0	0	0	0	0	0	0	0	0
0	0	0	0	0	0	0	1	1
0	0	0	0	0	0	1	0	2
				,				\downarrow
1	0	0	0	0	0	1	0	158
1	0	0	1	1	1	1	1	159

(9) Display Data Write

This command allows the 8-bit data to be written to the address specified by the display data RAM. After writing, column address or page address is automatically incremented +1 by the Display Data Input Direction Select command. This enables the MPU to write the display data continuously.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	0	0	0	1	1	1	0	1
1	1	0				Write	Data			

(10) Display Data Read

This command allows the 8-bit data to be read from the address specified by the display data RAM. After reading, column address or page address is automatically incremented +1 by the Display Data Input Direction select command. This enables the MPU to read multiple word data continuously.

It should be noted that one dummy reading is essential immediately after the column address or page address has been set. For details, see the description of "6.1.5 Access to display data RAM and internal register" in the Function Description. When the serial interface is used, display data cannot be read.

Α0	$\frac{E}{RD}$	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	0	0	0	1	1	1	0	0
1	0	1				Read	l Data			

(11) Display Data Input Direction Select

This command sets the direction where the display RAM address number is automatically incremented. For details, see the description of "6.2.3 Column address circuit" in the Function Description.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Direction
0	1	0	1	0	0	0	0	1	0	0	Column
										1	Page

(12) Column Address Set Direction

This command can reverse the relationship between the display RAM data column address and segment driver output shown in Fig. 6.5 and 6.6. So you can reverse the sequence of segment driver output pins using this command. When the display data is written or read, the column address is incremented by (+1) according to the column address given in Fig. 6.4 and 6.5. For details, see the description of "6.2.3 Column address circuit" in the Function Description.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Setting
0	1	0	1	0	1	0	0	0	0	0	Normal
										1	Reverse

(13) n-line Inversion Drive Register Set

This command sets the liquid crystal alternating drive reverse line count in the register to start line reverse driving operation. The line count to be set is 4 to 128 (32 states for each 4 lines. For details, see the description of "6.4 Display timing generation circuit" in the Function Description.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Reverse line count
0	1	0	0	0	1	1	0	1	1	0	Command
1	1	0	*	*	*	P4	P3	P2	P1	P0	Reverse line count

*: denote invalid bits.

P4	P3	P2	P1	P0	Reverse line count
0	0	0	0	0	4 (1 × 4)
0	0	0	0	1	8 (2 × 4)
		,	\downarrow		\
1	1	1	1	0	124 (31 × 4)
1	1	1	1	1	128 (32 × 4)

(14) n-line ON/OFF

This command provides ON/OFF control of n-line inverting drive.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	n-line
0	1	0	1	1	1	0	0	1	0	0	OFF
										1	ON

(15) Display Mode

This command sets the display mode. 4 gray-scale and binary display each have a different RAM configuration. For details, see the description of "6.2.1 Display Data RAM" in the Function Description.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Display mode
0	1	0	0	1	1	0	0	1	1	0	Command
Tota Shoo	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	0	*	*	*	*	*	*	P1	P0	Display mode

*: denote invalid bits.

P1	P0	Display mode
0	0	4gray-scale
0	1	Binary value

Set to 4 gray-scale (D1, D0) = (0, 0) at the time of resetting.

(16) Gray-scale Pattern Set

This command sets the level of gray-scale.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Gray-scale pattern
0	1	0	0	0	1	1	1	0	0	1	Command
1	1	0	*	P6	P5	P4	*	P2	P1	P0	Selection of gray-scale level

^{* (}P6, P5, P4) : Selects the level of gray-scale bit (1, 0)

^{* (}P2, P1, P0) : Selects the level of gray-scale bit (0, 1)

Gray-scale bit (1, 0)		P6	P5	P4		P2	P1	P0	Level of gray-scale
	ı	0	0	1	_	_	-	-	White
	_	0	1	0	_	_	_	_	
							\downarrow		\downarrow
	ı	1	1	0	_	_	-	_	Black
Gray-scale bit (0, 1)		P6	P5	P4		P2	P1	P0	Level of gray-scale
Gray-scale bit (0, 1)		P6	P5 -	P4 -	_	P2	P1	P0	Level of gray-scale White
Gray-scale bit (0, 1)		P6	P5 - -	P4 _ _					
Gray-scale bit (0, 1)	_ _	P6	P5 - -	P4		0		1	

(17) Area Scroll Set

This command sets the area scroll. When the binary display is selected by the Display Mode Set command, the scroll end line address becomes a two-byte parameter.

1 4 gray-scale display

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Area scroll
0	1	0	0	0	0	1	0	0	0	0	Command
1	1	0	*	*	*	*	*	*	P11	P10	Scroll mode
1	1	0	P27	P26	P25	P24	P23	P22	P21	P20	Scroll start line address
1	1	0	P37	P36	P35	P34	P33	P32	P31	P30	Scroll end line address
1	1	0	P47	P46	P45	P44	P43	P42	P41	P40	Scroll display line count

*: denote invalid bits.

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P11	P10	Scroll mode
0	0	0 (full screen)
0	1	1 (Upper)
1	0	2 (Lower)
1	1	3 (Central)

P27	P26	P25	P24	P23	P22	P21	P20	Scroll start line address
0	0	0	0	0	0	0	0	00H
0	0	0	0	0	0	0	1	01H
						\downarrow		\downarrow
1	0	0	0	0	0	1	0	82H
1	0	0	0	0	0	1	1	83H

P37	P36	P35	P34	P33	P32	P31	P30	Scroll end line address
0	0	0	0	0	0	0	0	00H
0	0	0	0	0	0	0	1	01H
						\downarrow		\downarrow
1	0	0	0	0	0	1	0	82H
1	0	0	0	0	0	1	1	83H

P47	P46	P45	P44	P43	P42	P41	P40	Scroll display line count
0	0	0	0	0	0	0	1	1
0	0	0	0	0	0	1	0	2
						\downarrow		\downarrow
1	0	0	0	0	0	1	1	131
1	0	0	0	0	1	0	0	132

2 Binary display

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Area scroll
0	1	0	0	0	0	1	0	0	0	0	Command
1	1	0	*	*	*	*	*	*	P11	P10	Scroll mode
1	1	0	P27	P26	P25	P24	P23	P22	P21	P20	Scroll start line address
1	1	0	P37	P36	P35	P34	P33	P32	P31	P30	Scroll end line address
1	1	0	*	*	*	*	*	*	*	P38	
1	1	0	P47	P46	P45	P44	P43	P42	P41	P40	Scroll display line count

*: denote invalid bits.

• Specifications on the parameters for scroll mode, scroll start line address and scroll display line count are the same as those on 4 gray-scale display.

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1st b	oyte
2nd	byte

	P37	P36	P35	P34	P33	P32	P31	P30 P38	Scroll end line address Binary value
	0	0	0	0	0	0	0	0	00H
	*	*	*	*	*	*	*	0	
Γ	0	0	0	0	0	0	0	1	01H
	*	*	*	*	*	*	*	0	
							\downarrow		\downarrow
Γ	0	0	0	0	0	1	1	0	106H
	*	*	*	*	*	*	*	1	
Γ	0	0	0	0	0	1	1	1	107H
	*	*	*	*	*	*	*	1	

(18) Duty Set Command

Liquid crystal drive at a lower power consumption is ensured by using this command to change the duty. Use of this command also allows display at a desired position on the panel (continuous COM pins on a 4-line basis). This command is used with a pair of the duty set parameter and start point (block) parameter, so be sure to set both parameters so that one of them will immediately follow the other.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Selected state
0	1	0	0	1	1	0	1	1	0	1	Duty set command
1	1	0	*	*	P15	P14	P13	P12	P11	P10	Duty set
1	1	0	*	*	P25	P24	P23	P22	P21	P20	Start point set

*: denote invalid bits.

• Duty set

Duty can be set in the range from 1/4 duty to 1/132 duty by 4 steps. Set to 1/132 duty after resetting.

P15	P14	P13	P12	P11	P10	Duty set
0	0	0	0	0	0	1/4 duty set
0	0	0	0	0	1	1/8 duty set
0	0	0	0	1	0	1/12 duty set
0	0	0	0	1	1	1/16 duty set
			\downarrow			\downarrow
0	1	1	1	1	1	1/128 duty set
1	0	0	0	0	0	1/132 duty set

• Start point (block) register set parameter

Use this parameter to set 6-bit data in the start point (block) register. Then one of 33 start point blocks will be determined.

* Use the Display Start Line Set command (6) for display scroll. Do not use this command for display scroll.

P25	P24	P23	P22	P21	P20	Start piont setting
0	0	0	0	0	0	0 (COM0 to 3)
0	0	0	0	0	1	1 (COM4 to 7)
0	0	0	0	1	0	2 (COM8 to 11)
		,	\downarrow			\downarrow
0	1	1	1	1	1	31 (COM124 to 127)
1	0	0	0	0	0	32 (COM128 to 131)

Set to 0 block (D7 to D0: ***00000) at the time of resetting

* Voltage optimum to liquid crystal drive is changed when the duty is changed. Use the electronic volume and set the voltage to get the optimum display.

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Duty command setup example

- 1. Duty 1/88 When 1 (COM4 to COM7) is specified as the start point (block) Display area COM4 to COM91
- 2. Duty 1/68 When 26 (COM104 to COM107) is specified as the start point (block) Display area COM104 to COM131 and COM0 to COM39
- * If the COM pin is not shared by the master and slave in the master/slave 2-chip operation (for vertical drive such as SEG132, COM80+COM80), the same duty must be used on the master and slave. Otherwise, display contrast will be different on the master and slave. When you want to disable display on either the master and slave, use the display OFF Mode Select command to set the side you want to disable, so that Vc level is output.

(19) Partial Display ON/OFF

The LCD partial display is turned on or off by this command.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Partial display
0	1	0	1	0	0	1	0	1	1	0	OFF
										1	ON

(20) Partial Display Set

This command sets the LCD partial display area. Duty is placed in the state selected by the Duty Set command. When partial display is switched by this command, liquid crystal drive voltage need not be changed. For details, see the description of "6.2.7 Partial Display" in the Function Description.

Α0	$\frac{E}{RD}$	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Partial display
0	1	0	0	0	1	1	0	0	1	0	Command
1	1	0	P17	P16	P15	P14	P13	P12	P11	P10	Display start line
1	1	0	P27	P26	P25	P24	P23	P22	P21	P20	Display line count

P17	P16	P15	P14	P13	P12	P11	P10	Display start line
0	0	0	0	0	0	0	0	0
0	0	0	0	0	0	0	1	1
0	0	0	0	0	0	1	0	2
						\downarrow		\downarrow
1	0	0	0	0	0	1	0	131
1	0	0	0	0	0	1	1	132

P17	P16	P15	P14	P13	P12	P11	P10	Display start line
0	0	0	0	0	0	0	1	1
0	0	0	0	0	0	1	0	2
						\downarrow		\downarrow
1	0	0	0	0	0	1	1	131
1	0	0	0	0	1	0	0	132

^{*} The result of display start line added to display line count exceeding 132 should be disregarded.

(21) Read Modify Write

This command is paired with end command for use. If this command is entered, the column address is not changed by the Display Data Read command. It can be incremented +1 by the Display Data Read command alone. This state s retained until the End command is input. If the End command is input, the column address goes back to the address when the Read Modify Write command is input. This function reduces the MPU loads when changing the data repeated in the specific display area such as blinking cursor.

.D	ataShee	t4U. c om	R/W								D0
	A0	RD	WR	D7	D6	D5	D4	D3	D2	D1	D0
	0	1	0	1	1	1	0	0	0	0	0

^{*} A command other than display data Read/Write command can be used in the Read Modify Write mode. However, you cannot use the column address set command.

• Sequence for cursor display

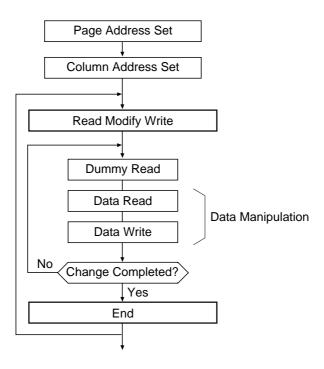


Fig. 7.2

(22) End

This command releases the read modify write mode and gets column address back to the initial address of the mode.

Α0	$\frac{E}{RD}$	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	1	1	1	0	1	1	1	0

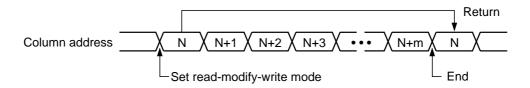


Fig. 7.3

www. (23) Built-in Oscillator Circuit ON/OFF

This command starts the built-in oscillator circuit operation. It is enabled only in the master operation mode (M/S = HIGH) when built-in oscillator circuit is valid (CLS = HIGH).

When the built-in power supply is used, the Oscillator Circuit ON command must be executed before the Power Control Set command. (See the description of "(16) power control command"). If the built-in oscillator circuit is turned off when the built-in power supply is used, display failure may occur.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Built-in oscillator circuit
0	1	0	1	0	1	0	1	0	1	0	OFF
										1	ON

(24) Built-in Oscillator Circuit Frequency Select

This command sets the built-in oscillator circuit frequency. The frequency can be selected whether the built-in oscillator circuit is turned on or off.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	fosc kHz	fcl kHz
0	1	0	0	1	0	1	1	1	1	1	Command	Command
1	1	0	*	*	*	*	P3	P2	P1	P0	Oscillation frequency	CL frequency

				Oscillation frequency	CL frequency fcL kHz
P3	P2	P1	P0	fosc kHz	102 11.12
0	0	0	0	120.0	fosc 120.0
0	0	0	1	100.0	fosc 100.0
0	0	1	0	88.0	fosc 88.0
0	0	1	1	76.0	fosc 76.0
0	1	0	0	120.0	fosc/2 = 60.0
0	1	0	1	100.0	fosc/2 = 50.0
0	1	1	0	88.0	fosc/2 = 44.0
0	1	1	1	76.0	fosc/2 = 38.0
1	0	0	0	120.0	fosc/4 = 30.0
1	0	0	1	100.0	fosc/4 = 25.0
1	0	1	0	88.0	fosc/4 = 22.0
1	0	1	1	76.0	fosc/4 = 19.0
1	1	0	0	120.0	fosc/8 = 15.0
1	1	0	1	100.0	fosc/8 = 12.5
1	1	1	0	88.0	fosc/8 = 11.0
1	1	1	1	76.0	fosc/8 = 9.5

(D7 to D0: ****0000) is set after resetting.

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^{*} The above-mentioned value is a Typ. value at 25° C. There is a tolerance of $\pm 12\%$ at 25° C.

(25) Power Control Set

This command sets the built-in power supply circuit function. For details, see the description of "6.7 Power supply circuit" in the Function Description.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Selected state
0	1	0	0	0	1	0	0	1	0	1	Command
1	1	0	0	0	0	P4	P3	P2	P1	P0	Register set

P4	P3	P2	P1	P0	Selected state
1	1				Triple step-up
1	0				Double step-up
0	1				Vout = Vdd
		0			Step-up: OFF
		1			Step-up: ON
			0		Vc: OFF
			1		Vc: ON
				0	LCD voltage: OFF
				1	LCD voltage: ON

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S1D15E06D00B*: (LCD voltage: V2, V1, MV1)

S1D15E06D00B*: (LCD voltage: V3, V2, V1, MV1, MV2)

An internal clock is required to operate the built-in power supply circuit. During the operation of the built-in power supply circuit, be sure that the internal clock is present inside.

If the built-in oscillator circuit is used, execute the built-in oscillator circuit ON command before the power control set command. If an external oscillator circuit is used, operate the external oscillator circuit before the power control set command.

If the internal clock is cut off during the operation of the built-in power supply circuit, display failure may occur. To avoid this, do not cut it off.

In the slave operation mode, only the parameters (D7 to D0 : ****00000) can be used with the power control set command. Do not use any other parameter.

100ms or more should be kept from VC regulator circuit ON to LCDV circuit ON.

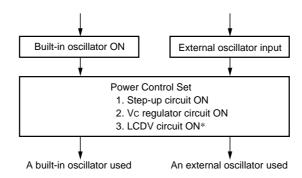


Fig. 7.4

(26) Step-up CK Frequency Select

This command selects the step-up CK and step-down CK frequencies.

Α0	$\frac{E}{RD}$	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	
0	1	0	0	1	0	0	0	0	0	1	Command
1	1	0	*	P6	P5	P4	*	P2	P1	P0	Register

^{*:} denote invalid bits.

(fosc/32) is set after resetting.

Step-up CK

P6 P5 P4 P2 P1 P₀ Step-up CK 0 1 1 fosc/8 1 0 0 fosc/16 1 0 1 fosc/32 \downarrow 1 1 0 fosc/64 1 1 1 fosc/128

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It should not use the following. (P2, P1, P0) = (0, 0, 0), (0, 0, 1), (0, 1, 0)

Step-down CK

*	P6	P5	P4	*000	P2	P1	P0	Step-down CK
_	0	1	1	_	-	-	_	fosc/8
-	1	0	0	_	_	-	_	fosc/16
_	1	0	1	_	_	_	_	fosc/32
	1	1	0			\downarrow		fosc/64
_	1	1	1	_	_	_	_	fosc/128

It should not use the following. (P6, P5, P4) = (0, 0, 0), (0, 0, 1), (0, 1, 0)* For S1D15E06D00B*, the step-down CK register is disabled.

(27) Liquid Crystal Drive Voltage Select

The liquid crystal drive voltage range issued from the liquid crystal drive voltage regulating circuit is selected from 3 states by this command.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Vc voltage output range
0	1	0	0	0	1	0	1	0	1	1	Command
1	1	0	*	*	*	*	*	*	P1	P0	Register

*: denote invalid bits.

P1	P0	Vc voltage output range
0	0	1.77 to 3.50 V
1	0	2.53 to 5.00 V
1	1	3.54 to 7.00 V

Vc voltage output range, 1.77 to 3.50V, (D1, D0) = (0, 0) is set after resetting.

(28) Electronic Volume

This command controls liquid crystal drive voltage VC issued from the built-in liquid crystal power supply voltage regulating circuit, and adjusts the liquid crystal display density. For details, see the description of "6.6.2 Voltage Regulating Circuit" in the Function Description.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	
0	1	0	1	0	0	0	0	0	0	1	Command
1	1	0	*	P6	P5	P4	P3	P2	P1	P0	Register

*: denote invalid bits.

• Electronic Volume Register Set

When a 7-bit data to the electronic volume register is set by this command, liquid crystal drive voltage VC assumes one state out of voltage values in 128 states.

After this command is input, and the electronic volume register is set, the electronic volume mode is reset.

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P6	P5	P4	P3	P2	P1	P0	Vc
0	0	0	0	0	0	0	Smaller
0	0	0	0	0	0	1	
0	0	0	0	0	1	0	
		`					\downarrow
1	1	1	1	1	1	0	
1	1	1	1	1	1	1	Larger

*: denote invalid bits.

• Electronic volume register set sequence

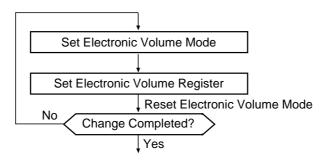


Fig. 7.5

(29) Discharge ON/OFF

This command discharges the capacitors connected to the power supply circuit. This command is used when the system power of this IC (S1D15E06 series) is turned off, and the duty is changed. See the description of (3) Power Supply OFF and (4) Changing the Duty in the Instruction Setup: Reference.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Setting
0	1	0	1	1	1	0	1	0	1	0	Discharge OFF
										1	Discharge ON

* If this command is executed when the external power supply is used, a large current may flow to damage the IC. If external power supply is used to drive liquid crystal, be sure to turn off the external power supply before executing this command.

(30) Power Saving

This command establishes the power save mode, thereby ensuring a substantial reduction of current consumption.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Power save mode
0	1	0	1	0	1	0	1	0	0	0	OFF
										1	ON

In the power save mode, display data and operation before power saving are maintained. Access to the display data RAM from the MPU is also possible. The current consumption is reduced to the value close to static current if all operations of the LCD display system are stopped and there is no access from the MPU.

In the power save mode, the following occurs:

Stop of oscillator circuit

Stop of LCD power supply circuit

Stop of all liquid crystal drive circuit (Vss level output is issued as the segment and common driver output).

The power save OFF command releases the power save mode. The system goes back to the state before the power save mode.

* When the external power supply is used, it is recommended to stop the external power supply circuit function when the power save mode is started. For example, when each level of the liquid crystal drive voltage is given from the external resistive divider circuit, it is recommended to add a circuit to cut off the current flowing to the resistive divider circuit when power save function is started. The S1D15E06 series has a liquid crystal display blanking control control pin DOF, and the level goes LOW when power save function is started. You can use the DOF output to stop the external power supply circuit function.

(31) Temperature Gradient Set

The 3-bit data of this command is used to set the temperature gradient characteristics of the liquid crystal drive voltage output from the built-in power supply circuit from eight states to one state. The temperature gradient of the liquid crystal drive voltage can be set according to the liquid crystal temperature gradient to be used. This eliminates the need of a temperature characteristics regulating circuit to be installed outside this IC (S1D15E06 series).

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Temperature gradient [%/°C]
0	1	0	0	1	0	0	1	1	1	0	Command
1	1	0	*	*	*	*	*	P2	P1	P0	Register

*: denote invalid bits.

P2	P1	P0	Temperature gradient [%/°C]
0	0	0	-0.06
0	0	1	-0.08
0	1	0	-0.10
0	1	1	-0.11
1	0	0	-0.13
1	0	1	-0.15
1	1	0	-0.17
1	1	1	-0.18

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(D7 to D0: *****000) is set after resetting. *: denote invalid bits.

(32) Status Read

This command reads out the temperature gradient select bit set on the register.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Temperature gradient [%/°C]
0	1	0	1	0	0	0	1	1	1	0	Command
1	0	1	*	*	*	*	*	P2	P1	P0	Register

*: denote invalid bits.

P2	P1	P0	Temperature gradient [%/°C]
0	0	0	-0.06
1	0	0	-0.08
0	1	0	-0.10
1	1	0	-0.11
0	0	1	-0.13
1	0	1	-0.15
0	1	1	-0.17
1	1	1	-0.18

(33) Reset

This command resets the column address, page address, read modify write mode and test mode without giving adverse effect to the display data RAM. For details, see the description of "6.8 Reset" in Function Description. Resetting is carried out after the reset command has been input.

Α0	E RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	1	1	1	0	0	0	1	0

Initialization upon application of power supply is carried out by the reset signal to the \overline{RES} pin. The reset command cannot be used for this purpose.

(34) MLS drive selection command

These are the MLS drive selection commands. These commands changes over between the dispersive drive and nondispersive drive.

/. D	ataShee A0	t4U. E om RD	R/W WR	D7	D6	D5	D4	D3	D2	D1	D0	Temperature gradient [%/°C]
	0	1	0	1	0	0	1	1	1	0	0	Command
	1	1	0	*	*	*	*	P3	P2	P1	P0	Register

^{*} indicates the invalid bits.

Temperature gradient [%/°C]	P0	P1	P2	P3
Dispersive drive	0	0	0	0
Nondispersive drive	0	0	0	1

After resetting, nondispersive drive will be preset in 4 gradation indications. In case the B/W indication is selected after resetting, dispersive drive will be preset.

Dispersive drive and nondispersive drive are the LCD drive methods characteristic to the MLS drive.

The S1D15E06 Series is making 4 line MLS drive and, 4 times higher period selection voltage than that of the period being used for indication of 1 line in an ordinary drive (in case of 132 line indication, the period of 1/132 of 1 frame). In case of the dispersive drive, the selection signals will be output for four times, separately, within the period of 1 frame. With this dispersive drive method, it is possible to reduce the frame frequency as compared with the nondispersive drive method. Therefore, when it becomes necessary to reduce the current consumption, we recommend you to use this dive method. However, in case of the drive method where moving pictures are to be indicated, the indication may become flickered and this dispersive drive method is not suitable for indications of moving pictures.

(35) NOP

This is a Non-Operation command.

		R/W WR								
0	1	0	1	1	1	0	0	0	1	1

Note: S1D15E06 series maintains the operation status due to the command. However, when exposed to excessive external noise, internal status may be changed. This makes it necessary to take some measures which reduces noise generation in terms of installation or system configuration, or which protects the system against adverse effect of noise. To cope with sudden noise, it is recommended to refresh the operation status on a periodic basis.

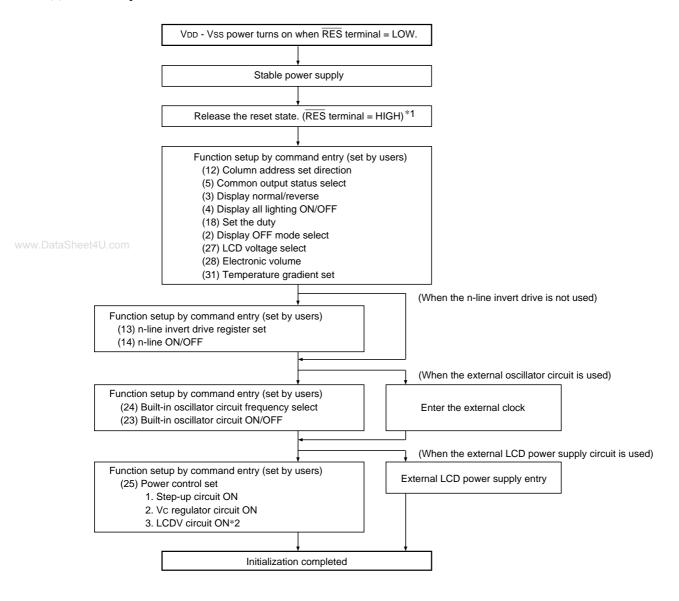
Table 7.1 Table of commands in S1D15E06 series

					Со	mma	and	code	•				
	Command	A0	RD	WR	D7	D6	D5	D4	D3	D2	D1	D0	Function
(1)	Display ON/OFF	0	1	0	1	0	1	0	1	1	1	0 1	LCD display ON/OFF control. 0: OFF, 1: ON
(2)	Display OFF Mode Select	0	1	0	1	0	1	1	1	1	1	0 1	Output level when the display is OFF and in the power save mode 0: Vss, 1: Vc
(3)	Display Normal /Reverse	0	1	0	1	0	1	0	0	1	1	0 1	LCD display normal/reverse 0: Normal, 1: Reverse
(4)	Display All Lighting ON/OFF	0	1	0	1	0	1	0	0	1	0	0 1	Display All Lighting 0: Normal display, 1: All ON
(5)	Common Output Status Select	0	1	0	1	1	0	0	0	1	0	0	Selects COM output scan direction. 0: Normal, 1: Reverse
(6)	Display Start Line Set	0	1	0	1	0	0	0	.1	0	1	0	Sets display start line.
		1 1	1 1	0 0	*	Disp *	lay :	start *	line *	addı *	ress *	\downarrow	When the display mode is binary, the parameter consists of two bytes.
(7) taSh	Page Address Set	0	1	0	1	0	1	1 Pa	0 ge a	0 ddre	0 ss	1	Sets the display RAM page address
(8)	Column Address Set	0 1	1 1	0 0	0	0 Co	0 Iumi	1 n Ad	0 dres	0 s Se	1 et	1	Sets the display RAM column address.
(9)	Display Data Write	0 1	1 1	0 0	0	0	0 Wı	1 rites	1 data	1	0	1	Writes data to the display RAM.
(10)	Display Data Read	0 1	1 0	0 1	0	0	0 Re	1 ads	1 data	1	0	0	Reads data to the display RAM.
	Display Data Input Direction Select	0	1	0	1	0	0	0	0	1	0	0 1	Display RAM data input direction 0: Column direction 1: Page direction
(12)	Column Address Set Direction	0	1	0	1	0	1	0	0	0	0	0	Compatible with display RAM address SEG output 0: Normal 1: Reverse
(13)	N-line inversion Drive Register Set	0 1	1 1	0 0	0	0	1	1 Inv	0 ert li	1 ne c	1 ount	0	Line invert drive. Sets the line count.
(14)	N-line ON/OFF	0	1	0	1	1	1	0	0	1	0	0	Resets the line invert drive. 0: N-line OFF 1: N-line ON
(15)	Display Mode	0	1 1	0	0	1	1	0	0	1	1 Mo	0 de	00: 4 gray-scale, 01: binary
(16)	Gray-scale Pattern Set	0 1	1 1	0 0	0	0 Gra	1 ay-s	1 cale	1 patte	0 ern	0	1	Selects the contrast of gray-scale bit (1,0) (0,1).
(17)	Area Scroll	0	1	0	0	0	0	1	0	0	0	0	
	Scroll Mode	1	1	0	*	*	*	*	*	*	Мо	de	When the display mode is binary,
	Scroll Start address	1	1	0				ddre					the end address consists of
	Scroll End address Display page count	1 1	1 1	0 0				ldres / pag		unt			two bytes.
(18)	Duty Set Command	0	1	0	0	1	1	, pa <u>c</u> 0	1	1	0	1	
(10)	Duty Set Command	U	'	U	*	*	'	•	ty co	•	U	'	
	Static spot (block) set				*	*	Sta	atic s			ck)		
(19)	Partial Display ON/OFF	0	1	0	1	0	0	1	0	1	1	0	Partial display ON/OFF 0: OFF, 1: ON
(20)	Partial Display Set Display Start line Display Line count	0	1	0	0	0		1 art lir ne co		0	1	0	
(21)	Read Modify Write	0	1	0	1	1	1	0	0	0	0	0	Increments the column address. Increments +1 in the write mode. Does not increment in the read mode.
(22)	End	0	1	0	1	1	1	0	1	1	1	0	Resets read modify write functions.
` '	Built-in Oscillator Circuit ON/OFF	0	1	0	1	0	1	0	1	0	1	0	Built-in oscillator circuit operation 0: OFF, 1: ON
. ,	Built-in Oscillator Circuit Frequency Select	0	1 1	0 0	0	1 *	0	1 *		1 que		1	
(25)	Power Control Set	0 1	1 1	0	0	0	1	0	0 Op	1 erati	0 on s	1 tate	Selects built-in power supply operation state.

						Cor	nma	nd o	code	•				
		Command	A0	RD	WR	D7	D6	D5	D4	D3	D2	D1	D0	Function
Ī	(26)	Step-up CK	0	1	0	0	1	0	0	0	0	0	1	
		Frequency Select	1	1	0	*		Fre	que	ncy				
	(27)		0	1	0	0	0	1	0	1	0	1	1	
		Voltage Select	1	1	0	*	*	*	*	*	*	Vc	range	
	(28)	Electronic Volume Mode Set	0	1	0	1	0	0	0	0	0	0	1	
		Electronic Volume	1	1	0	*	Ele	ctro	nic v	olun	ne			Vc output voltage is set to the electronic volume register. 128 states
-	(00)	Register Set				4		_					_	<u> </u>
	(29)	Discharge ON/OFF	0	1	0	1	1	1	0	1	0	1	0	Discharges Power supply circuit
													ļ	connection capacitor. 0: OFF (normal), 1: ON
	(30)	Power Save ON/OFF	0	1	0	1	0	1	0	1	0	0	0	Power Save 0: OFF, 1: ON
	(31)	Temperature	0	1	0	0	1	0	0	1	1	1	0	Sets to 8 steps.
		Gradient Select	1	1	0	*	*	*	*	* Te	empera	ture g	radient	
	(32)	Stator Read	0	1	0	1	0	0	0	1	1	1	0	Issues the temperature gradient
			1	0	1	*	*	*	*	*Ter	nperat	ure gr	adient	select bit.
www.D	(33)	Reset	0	1	0	1	1	1	0	0	0	1	0	Resets the column, page and address registers. Resets the read modify write function.
Ī	(34)	MLS drive selection	0	1	0	1	0	0	1	1	1	0	0	MLS drive method
			1	1	0	*	*	*	*	MLS	3 driv	e me	ethod	0 : Dispersive, 1 : Nondispersive
	(35)	NOP	0	1	0	1	1	1	0	0	0	1	1	Non-operation command

Instruction Setup Example (Reference)

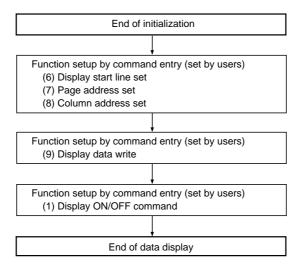
(1) Initial setup



Note: *1 Display data RAM contents are not determined even in the initialized state after resetting. See "6.7 Reset Circuit" in the "6. Function Description".

- *2 100ms or more should be kept from Vc regulator circuit ON to LCDV circuit ON.
- * Numerals in the command parenthesis correspond to the numerals of the items in Command Description.

(2) Data display

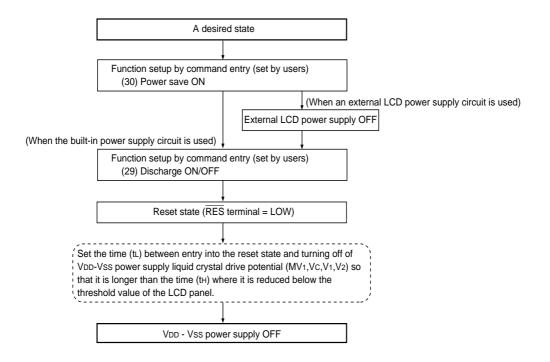


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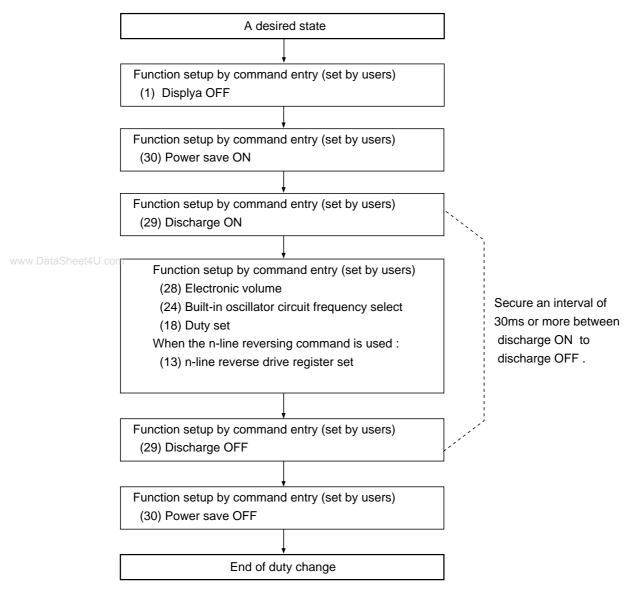
Note: * Display data RAM contents are not determined after end of initialization. Write data to all the Display data RAM used for display. See "9. Display data write" in the "7. Command Description".

(3) Power OFF



Note: * This IC controls the circuit of the liquid crystal drive power supply system using the VDD-VSS power supply circuit. If the VDD-VSS power supply is cut off with voltage remaining in the liquid crystal drive power supply system, voltage not controlled will be issued from the SEG and COM pins, and this may result in display failure. To avoid this, follow the above-mentioned power off sequence.

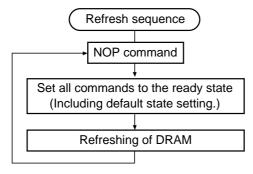
(4) How to change the duty



Note: * Execution of the above sequence causes display to be turned off temporarily (for the time from Power Saving command ON to Power Saving command OFF plus 200 ms (frame frequency 60Hz) upon switching of the duty. Temporary display failure may occur if Duty Change command is executed during liquid crystal display without executing the above-mentioned setup example. Follow the setup example when the duty is changed as discussed above.

(5) Refresh

It is recommended that the operating modes and display contents be refreshed periodically to prevent the effect of unexpected noise.



8. ABSOLUTE MAXIMUM RATINGS

Table 8

Vss = 0V unless otherwise specified.

Item		Symbol	Specified value	Unit
Power voltage (1)		Vdd	-0.3 to +4.0	V
Power voltage (2)		V3, VOUT	-0.3 to +17.0	
Power voltage (3)		V2, V1, VC, MV1, MV2	-0.3 to V ₃	
Input voltage		Vin	-0.3 to VDD+0.3	
Output voltage		Vo	-0.3 to VDD+0.3	
Operating temperature		Topr	-40 to +85	°C
Storage temperature	TCP	Tstr	-55 to +100	
	bare chip		-55 to +125	

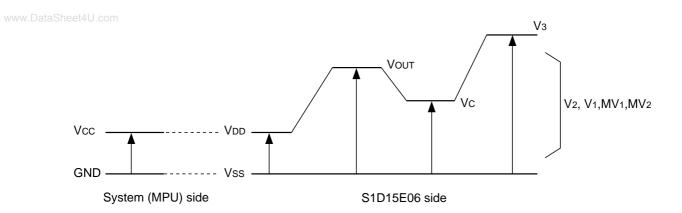


Fig. 8

Notes: 1. Voltages V3, V2, V1, VC, MV1, MV2 and MV3 (VSS) must always meet the conditions of $V3 \ge V2 \ge V1 \ge VC \ge MV1 \ge MV2 \ge MV3$ (VSS).

- 2. Voltage Vou⊤ must always meet the conditions of Vouт≥VDD and Vouт≥VC.
- 3. If the LSI has been used in excess of the absolute maximum rating, it may be subjected to permanent breakdown. So in the normal operation, the LSI is preferred to be used under the condition of electrical characteristics. If this condition is not met, LSI operation error may occur and LSI reliability may be deteriorated.

9. DC CHARACTERISTICS

 $Vss = 0V,\, VdD = 2.7V \pm 10\%$ and Ta = -40 to $+85^{\circ}C$ unless otherwise specified.

Table 9.1

					Spe	cified va	alue		Applicable
Itei	m	Symbol	Cond	litions	Min.	Тур.	Max.	Unit	pin
Working voltage (1)	Operation enabled	Vdd			1.7	_	3.6	V	VDD *1
Working voltage (2)	Operation recommended	Vout			Vdd	_	16.0		Vouт
Working voltage (3)	Operation enabled	Vз	Applicable	e to	3.4	_	14.0		V3 *2
	Operation enabled	Vc	S1D15E06	D01****	1.7	_	7.0		Vc
	Operation enabled	V2			Vc	_	Vз		V2
	Operation enabled				Vc	_	V3		V1
	Operation enabled	MV1			Vss	_	Vc		MV1
	Operation enabled	MV2			Vss	_	Vc		MV2
Working voltage (4)	Operation enabled	Vз	Applicable	e to	3.4	_	16.0		V3 *2
	Operation enabled	Vc	S1D15E06	D03****	1.7	_	8.0		Vc
ataSheet4U.com	Operation enabled	V2			Vc	_	Vз		V2
	Operation enabled	V1			Vc	_	Vз		V1
	Operation enabled	MV1			Vss	_	Vc		MV1
	Operation enabled	MV2			Vss	_	Vc		MV2
High-level input volta	age	VIHC	VDD=1.7\	/ to 3.6V	0.8×VDD	_	Vdd		*3
Low-level input volta	ge	VILC			Vss	_	0.2×VDD		*3
High-level output vol	tage	Vонс	VDD=1.7V	Iон=-0.25mA	0.8×VDD	_	Vdd		*4
Low-level output volt	tage	Volc	to 3.6V	IoL=0.25mA	Vss	_	0.2×VDD		*4
Input leak current		ILI	VIN=VDD	or Vss	-1.0	_	1.0	μΑ	*5
Output leak current		ILO			-3.0	_	3.0		*6
LCD driver ON resis	tance	Ron	Ta=25°C	V3=7.2V	_	1.5	2.3	kΩ	SEGn
				V3=4.8V	_	3.0	4.6		COMn *7
Static current consu	mption	IDDQ	Ta=25°C	VDD=3.6V	_	0.2	5.0	μΑ	Vdd
		l3Q		V3=14.0V	_	1.0	5.0		Vз
Input pin capacity		CIN	Ta=25°C,	f=1MHz	_	20	25	pF	
Oscillation	Built-in oscillation	fosc	Ta=25°C		110	120	130	kHz	*8
frequency			Max. freq	uency					

Table 9.2

	Item			Spe	ecified va	lue		Applicable
			Conditions	Min.	Тур.	Max.	Unit	pin
power	Input voltage	V _{DD}	Double boosting Triple boosting	1.7 1.7	_	3.6 3.6	V	Vdd
t-in p circu	Boosted output voltage (1)	Vоит	S1D15E06D01****	_	_	14.0		Vout
Built-in circ	Boosted output voltage (2)	Vоит	S1D15E06D03****	_	_	16.0		Vout
Ш	Working voltage for voltage control circuit	Vc		1.8	_	8.0		Vc *9

Dynamic current consumption (1): Built-in power is turned on during display.

Ta=25°C

This is the current consumed by the entire IC including the built-in power supply.

Display mode in 4 gray-scale at fFR = 80Hz

Table 9.3 Display entirely in white Code: Iss (1)

VDD	Boosting	V ₃ Voltage	1/132	DUTY	1/100	DUTY	Unit	Remarks
VDD	Boosing	vs voitage	Тур.	Max.	Тур.	Max.	Offic	Kelliaiks
2.7V	Triple	10V	68	112	67	111	μΑ	*10
		12V	81	134	71	117		
3.6V	Double	10V	73	121	63	104		
	Triple	12V	93	154	83	137		

Display mode in 4 gray-scale at ffr = 80Hz

Table 9.4 Display: Heavy load display Code: Iss (1)

VDD	Boosting	V ₃ Voltage	1/132	DUTY	1/100	DUTY	Unit	Remarks
V DD	boosting	vs voitage	Тур.	Max.	Тур.	Max.	Oill	IVEIII AI KS
2.7V	Triple	10V	241	400	187	310	μΑ	*10
		12V	373	619	313	519		
3.6V	Double	10V	189	313	146	242		
	Triple	12V	380	630	314	521		

Display mode in binary at ffr = 60Hz

Table 9.5 Display entirely in white Code: ISS (1)

VDD	Boosting	V ₃ Voltage	1/132	DUTY	1/100	DUTY	Unit	Remarks
V DD	Doosting	vs voitage	Тур.	Max.	Тур.	Max.) iii	INGIIIAI KS
2.7V	Triple	10V	65	108	50	83	μΑ	*10
		12V	72	120	56	93		
3.6V	Double	10V	57	95	44	73		
	Triple	12V	82	136	63	104		

Display mode in binary at fFR = 60Hz

Table 9.6 Display Heavy load display Code: ISS (1)

VDD	Boosting	V ₃ Voltage	1/132	DUTY	1/100	DUTY	Unit	Remarks
VDD	Boosing	vs voitage	Тур.	Max.	Тур.	Max.	Oilit	Kelliaiks
2.7V	Triple	10V	188	312	135	224	μΑ	*10
		12V	313	520	226	300		
3.6V	Double	10V	150	249	108	143		
	Triple	12V	322	534	232	308		

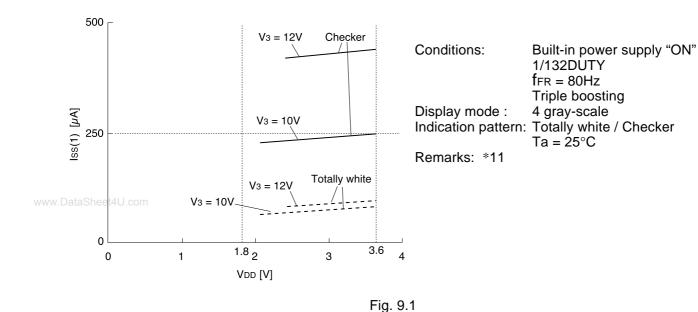
Current consumption under power saving mode: Vss = 0V, VDD = 3.3V, Ta = 25°C

Table 9.7

. D	ataSheat4LLcom	Symbol	Condition	Spe	cified v	cified value		Remarks
	ltem	Symbol	Condition	Min.	Тур.	Max.	Unit	Keiliaiks
	Sleep state	IDDS1		_	0.2	5	μΑ	

[Reference Data 1]

• Dynamic current consumption (1) during LCD display when internal power is used



[Reference Data 2]

• Dynamic current consumption (2) during LCD display when internal power is used

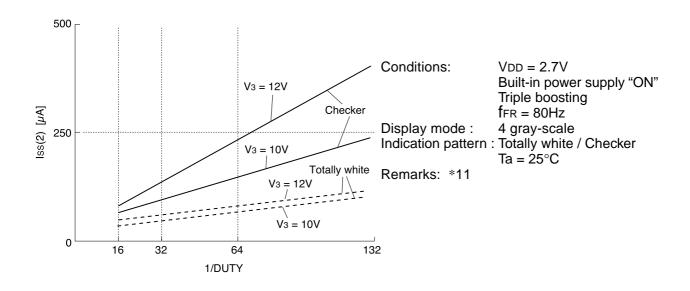
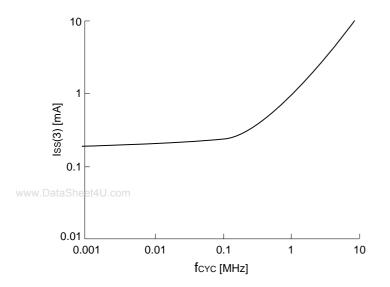


Fig. 9.2

[Reference Data 3]

• Dynamic current consumption (3) during access



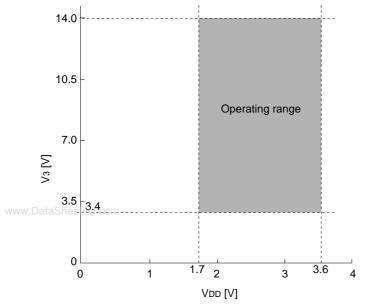
Indicates the current consumption when the checker pattern is always written by fcyc. When not accessed, only Iss(1) remains.

Conditions: Built-in voltage used Triple boosting V_3 = 12.0V, V_{DD} = 2.7V T_a = 25°C f_{FR} =80Hz 1/132 Duty

Fig. 9.3

[Reference Data 4]

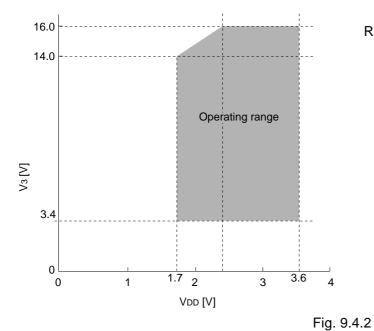
• Operating voltage range (S1D15E06D01****)



Remarks: *2

Fig. 9.4.1

• Operating voltage range (S1D15E06D03****)



Remarks: *2

• Relationship between oscillation frequency fosc, display clock frequency fcL and liquid crystal frame fFR

Table 9.8

Item	fcL	Display mode	fFR
Built-in oscillator circuit used	See p. 24	Binary display 4 gray-scale	(fcL × DUTY)/4 (fcL × DUTY)/8
Built-in oscillator circuit not used	External input (fcL)	Binary display 4 gray-scale	(fcL × DUTY)/4 (fcL × DUTY)/8

(ffr indicates the cycle of rewriting one screen; it does not indicate FR signal cycle.)

[Asterisked references]

- *1. Does not guarantee if there is an abrupt voltage variation during MPU access.
- *2. For VDD and V3 system operating voltage range, see Fig. 9.5. Applicable when the external power supply is used.
- *3. $\underline{A0}$, D0 to D5, D6(SCL), D7(SI), \overline{RD} (E), \overline{WR} (R/W), $\overline{CS1}$, CS2, CLS, CL, FR, F1, F2, CA, M/S, C86, P/S, \overline{DOF} , RES and TEST pins
- *4. D0 to D7, FR, DOF, CL, F1, F2 and CA pins
- *5. A0, $\overline{RD}(E)$, $\overline{WR}(R/\overline{W})$, $\overline{CS1}$, CS2, CLS, M/S, C86, P/S, \overline{RES} and TEST pins
- *6. Applicable when D0 to D5, D6(SCL), D7(S1), CL, FR, \overline{DOF} , F1, F2 and CA pins have a high impedance.
- *7. Indicates the resistance when 0.1V voltage is applied between the output pin SEGn or COMn and each power supply (V2, V1, VC, MV1, MV2).

 RON =0.1V/ΔI (where ΔI denotes current when 0.1V is applied when power is on).
- *8. For the relationship between oscillation frequency and frame frequency, see Table 9.8. The standard values of the external input item are recommended ones.
- *9. The VC voltage regulating circuit should be adjusted within the electronic volume operation range.
- *10. Indicates the current consumed by a single IC when display is on. Use the electronic volume for voltage regulation. Also use the internal oscillator circuit. The current due to LCD panel capacity and wiring capacity is not included. Applicable when there is access from the MPU.

10. TIMING CHARACTERISTICS

(1) System path read/write characteristics 1 (80 system MPU)

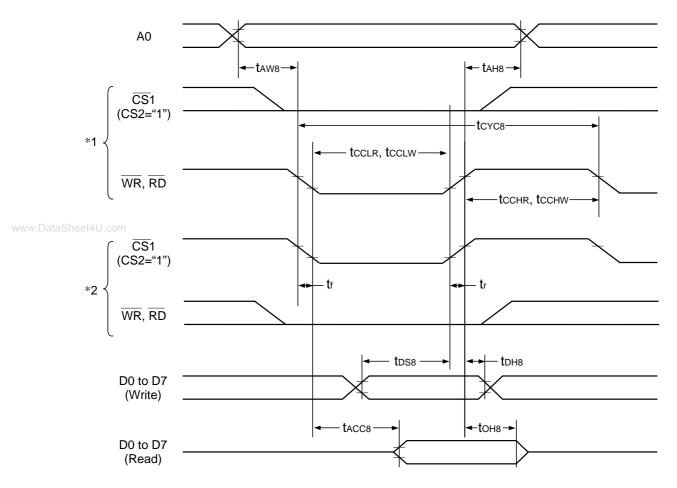


Fig. 10.1

Table 10.1.1

 $[VDD = 3.0V \text{ to } 3.6V, Ta = -40 \text{ to } +85^{\circ}C]$

Parameter	Signal	Symbol	Condition	Specifie	ed value	Unit
Farameter	Signal	Syllibol	Condition	Min.	Max.	Onit
Address hold time Address setup time	A0	t ah8 t aw8		0 0	_	ns
System write cycle time System read cycle time	WR RD	twcyc8		200 300	_	
Control LOW-pulse width (Write) Control LOW-pulse width (Read) Control HIGH-pulse width (Write) Control HIGH-pulse width (Read)	WR RD WR RD	tccLw tccLR tccHw tccHR		60 100 60 100		
Data setup time Data hold time	D0 to D7	t _{DS8} t _{DH8}		20 10	_	
RD access time Output disable time		t ACC8 t OH8	CL=100pF	_ 10	80 80	

Table 10.1.2

 $[VDD = 2.4V \text{ to } 3.0V, Ta = -40 \text{ to } +85^{\circ}C]$

Parameter	Signal	Symbol	Condition	Specifie	ed value	Unit
Parameter	Signal	Symbol	Condition	Min.	Max.	Unit
Address hold time Address setup time	A0	tah8 taw8		0 0	_	ns
System write cycle time System read cycle time	WR RD	twcyc8 trcyc8		300 400	_	
Control LOW-pulse width (Write) Control LOW-pulse width (Read) Control HIGH-pulse width (Write) Control HIGH-pulse width (Read)	WR RD WR RD	tccLw tccLR tccHw tccHR		80 200 80 200	 - - -	
Data setup time Data hold time	D0 to D7	tds8 tdh8		30 15		
RD access time Output disable time		t acc8 t oн8	CL=100pF	— 10	120 120	

Table 10.1.3

 $[VDD = 1.7V \text{ to } 2.4V, Ta = -40 \text{ to } +85^{\circ}C]$

Parameter	Signal	Symbol	Condition	Specifie	ed value	Unit
Farameter	Signal	Symbol	Condition	Min.	Max.	Unit
Address hold time Address setup time	A0	tah8 taw8		0 0	_	ns
System write cycle time System read cycle time	WR RD	twcyc8 trcyc8		400 600	_	
Control LOW-pulse width (Write) Control LOW-pulse width (Read) Control HIGH-pulse width (Write) Control HIGH-pulse width (Read)	WR RD WR RD	tcclw tcclr tcchw tcchr		100 250 140 250	_ _ _ _	
Data setup time Data hold time	D0 to D7	tds8 tdh8		40 20	_	
RD access time Output disable time		t ACC8 t OH8	CL=100pF	— 10	200 200	

^{*1.} This is in case of making the access by \overline{WR} and \overline{RD} , setting the $\overline{CS1} = LOW$.

^{*2.} This is in case of making the access by $\overline{CS1}$, setting the \overline{WR} , $\overline{RD} = LOW$.

^{*3.} Input signal rise and fall time (tr, tf) must not exceed 15 ns. When the system cycle time is used at a high speed, it is specified by $(tr + tf) \le (tCYC8 - tCCLW - tCCHW)$ or $(tr + tf) \le (tCYC8 - tCCLR - tCCHR)$.

^{*4.} Timing is entirely specified with reference to 20% or 80% of VDD.

^{*5.} $\underline{\text{tCCLW}}$ and $\underline{\text{tCCLR}}$ are specified in terms of the overlapped period when $\overline{\text{CS1}}$ is at LOW (CS2 = HIGH) level and $\overline{\text{WR}}$ and $\overline{\text{RD}}$ are at LOW level.

(2) System path read/write characteristics 2 (68 system MPU)

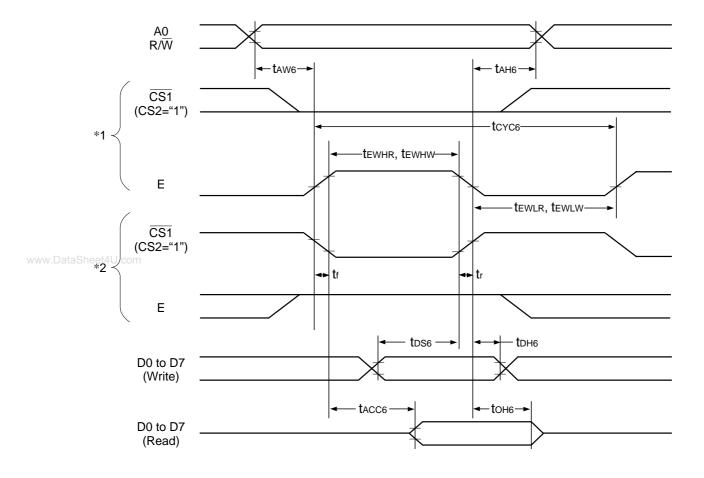


Fig. 10.2

Table 10.2.1

 $[VDD = 3.0V \text{ to } 3.6V, Ta = -40 \text{ to } +85^{\circ}C]$

Parameter		Signal	Symbol	Condition	Specifie	ed value	Unit
Parameter		Signal	Symbol	Condition	Min.	Max.	Unit
Address hold time Address setup time		A0	t AH6 t AW6		0 0	_	ns
System write cycle time System read cycle time		E	twcyc6 trcyc6		200 300	_	
Data setup time Data hold time		D0 to D7	tds6 tdh6		20 10	_	
Access time Output disable time			tacc6 toh6	CL=100pF	— 10	80 80	
Enable HIGH-pulse width	Read Write	E	tewhr tewhw		100 60	_	
Enable LOW-pulse width	Read Write	E	tewlr tewlw		100 60	_	1

Table 10.2.2

 $[VDD = 2.4V \text{ to } 3.0V, Ta = -40 \text{ to } +85^{\circ}C]$

Parameter		Signal	Symbol	Condition	Specified value		Unit	
Parameter		Signal	Symbol	Condition	Min.	Max.	Oilit	
Address hold time Address setup time		A0	t ah6 t aw6		0 0		ns	
System write cycle time System read cycle time		E	twcyc6 trcyc6		300 400	_		
Data setup time Data hold time		D0 to D7	tds6 tdh6		30 15	_		
Access time Output disable time			tacc6 toh6	CL=100pF	— 10	120 120		
Enable HIGH-pulse width	Read Write	E	tewhr tewhw		150 80	_		
Enable LOW-pulse width	Read Write	E	tewlr tewlw		150 80	_		

Table 10.2.3

 $[VDD = 1.7V \text{ to } 2.4V, Ta = -40 \text{ to } +85^{\circ}C]$

Parameter		Cianal	Symbol	Condition	Specifie	ed value	Unit
Parameter		Signal	Symbol	Condition	Min.	Max.	
Address hold time Address setup time		A0	tah6 taw6		0 0	_	ns
System write cycle time System read cycle time		E	twcyc6 trcyc6		400 600	_	
Data setup time Data hold time		D0 to D7	tds6 tdh6		40 20	_	
Access time Output disable time			tACC6 tOH6	CL=100pF	_ 10	200 200	
Enable HIGH-pulse width	Read Write	E	tewhr tewhw		250 100	_	
Enable LOW-pulse width	Read Write	E	tewlr tewlw		250 140	_	

- *1 This is in case of making the access by E, setting the $\overline{CS1} = LOW$.
- *2 This is in case of making the access by $\overline{CS1}$, setting the E = HIGH.
- *3 The rise time and the fall time (tr & tf) of the input signals should be set to 15ns or less. When it is necessary to use the system cycle time at high speed, the rise time and the fall time should be so set to conform to $(tr+tf) \le (tcvc6-tewlw-tewhw)$ or $(tr+tf) \le (tcyc6-tewlr-tewhr)$.
- *4 All the timing should basically be set to 20% and 80% of the "VDD".
 *5 tewlw, tewlr should be set to the overlapping zone where the CS1 is on the LOW level (CS2 = HIGH level) and where the E is on the HIGH level.

(3) Serial interface

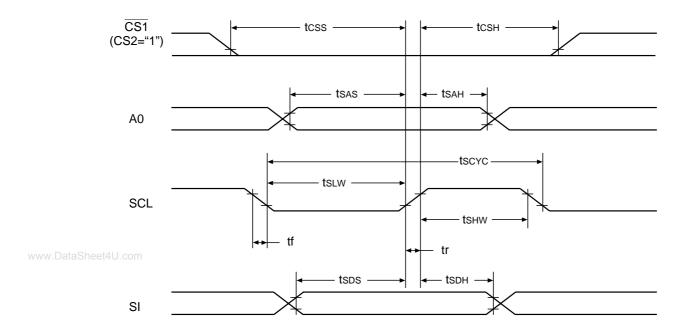


Figure 10.3

Table 10.3.1

 $[VDD = 3.0V \text{ to } 3.6V, Ta = -40 \text{ to } +85^{\circ}C]$

Parameter	Signal	Symbol	Condition	Specified value		Unit
raiailletei	Signal	Syllibol	Condition	Min.	Max.	Onit
Serial clock period SCL HIGH pulse width SCL LOW pulse width	SCL	tscyc tshw tslw		100 40 40	_ _ _	ns
Address setup time Address hold time	A0	tsas tsah		80 80	_	
Data setup time Data hold time	SI	tsds tsdh		20 20	_	
CS-SCL time	CS	tcss tcsн		80 150	_	

Table 10.3.2

 $[VDD = 2.4V \text{ to } 3.0V, Ta = -40 \text{ to } +85^{\circ}C]$

Parameter	Signal	Symbol	Condition	Specified value		Unit
raiailletei	Signal	Syllibol	Condition	Min.	Max.	
Serial clock period SCL HIGH pulse width SCL LOW pulse width	SCL	tscyc tshw tslw		125 50 50		ns
Address setup time Address hold time	A0	tsas tsah		100 100	_	
Data setup time Data hold time	SI	tsds tsdh		30 30	_	
CS-SCL time	CS	tcss tcsн		100 200	_	

Table 10.3.3

[VDD = 1.7V to 2.4V, $Ta = -40 \text{ to } +85^{\circ}\text{C}$]

Parameter	Signal	Symbol	Condition	Specified value		Unit
raiailletei	Signal	Syllibol	Condition	Min.	Max.	
Serial clock period SCL HIGH pulse width SCL LOW pulse width	SCL	tscyc tshw tslw		154 60 60		ns
Address setup time Address hold time	A0	tsas tsah		120 140	_	
Data setup time Data hold time	SI	tsds tsdh		40 40	_	
CS-SCL time	CS	tcss tcsн		120 350	_	

^{*1.} Input signal rise and fall time (tr, tf) must not exceed 15 ns.
*2. Timing is entirely specified with reference to 20% or 80% of VDD.

(4) Display control output timing

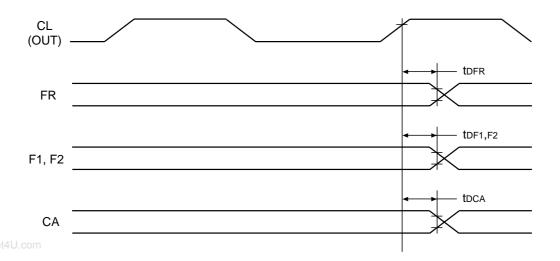


Fig. 10.4

Table 10.4.1

[VDD = 3.0V to 3.6V, Ta = -40 to $+85^{\circ}C$]

Parameter	Signal Symbol		Condition	Sp	Unit		
	Signal	Symbol	Condition	Min.	Тур.	Max.	
FR delay time	FR	t DFR	CL = 50pF	_	125	312	ns
F1, F2 delay time	F1, F2	t DF1, t F2		_	125	312	ns
CA delay time	CA	t DCA			125	312	ns

Table 10.4.2

 $[VDD = 2.4V \text{ to } 3.0V, Ta = -40 \text{ to } +85^{\circ}C]$

Parameter	Signal Symbol		Condition	Sp	Unit		
	Signal	Syllibol	Condition	Min.	Тур.	Max.	Oilit
FR delay time	FR	t DFR	CL = 50pF	_	150	360	ns
F1, F2 delay time	F1, F2	t DF1, t F2		_	150	360	ns
CA delay time	CA	t DCA		_	150	360	ns

Table 10.4.3

[VDD = 1.7V to 2.4V, Ta = -40 to $+85^{\circ}C$]

Parameter	Signal Symbol		Condition	Sp	Unit		
	Signal	Syllibol	Condition	Min.	Тур.	Max.	Oilit
FR delay time	FR	t DFR	CL = 50pF	_	225	514	ns
F1, F2 delay time	F1, F2	t DF1, t F2		_	225	514	ns
CA delay time	CA	t DCA		_	225	514	ns

^{*1.} Valid only in master operation

^{*2.} Timing is entirely specified with reference to 20% or 80% of VDD.

(5) Reset input timing

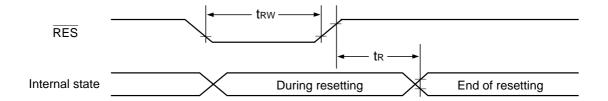


Fig. 10.5

Table 10.5.1

[VDD = 3.0V to 3.6V, Ta = -40 to $+85^{\circ}C$]

DataSheet4 Parameter	Signal	Symbol	Condition	Sp	Unit		
	Signal	Syllibol	Condition	Min.	Тур.	Max.	Oilit
Reset time		t R		_	_	0.5	μs
Reset LOW pulse width	RES	t RW		0.5	_	_	

Table 10.5.2

[VDD = 2.4V to 3.0V, Ta = -40 to $+85^{\circ}C$]

Parameter	Signal Symbol	Symbol	I Condition	Sp	Unit		
	Signal	Syllibol	Condition	Min.	Тур.	Max.	Oille
Reset time		t R		_	_	1.0	μs
Reset LOW pulse width	RES	trw		1.0	_		

Table 10.5.3

[VDD = 1.7V to 2.4V, $Ta = -40 \text{ to } +85^{\circ}C$]

Parameter	Signal	Symbol	Condition	Sp	ecified va	lue	Unit
Parameter	Signal	Syllibol	Condition	Min.	Тур.	Max.	
Reset time		t R		_	_	1.5	μs
Reset LOW pulse width	RES	trw		1.5	_	_	

*1. Timing is entirely specified with reference to 20% or 80% of VDD.

11. MPU INTERFACE (Reference Example)

The S1D15E06 series can be connected to the 80 series MPU and 68 series MPU. Use of a serial interface allows operation with a smaller number of signal lines.

You can expand the display area using the S1D15E06 series as a multi-chip. In this case, the IC to be accesses can be selected individually by the chip select signal. After initialization by the \overline{RES} pin, each input terminal of the S1D15E06 series must be placed under normal control.

(1) 80 series MPU

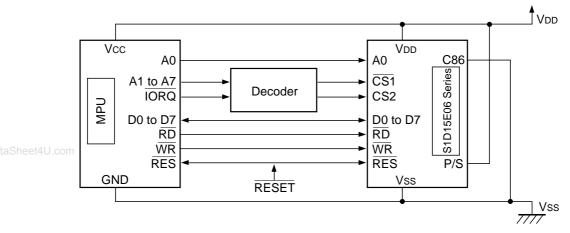


Fig. 11.1

(2) 68 series MPU

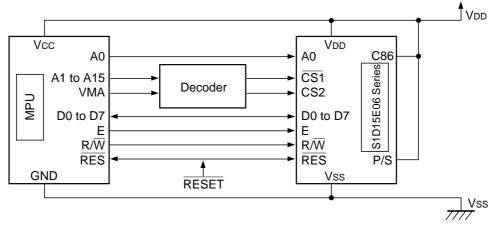
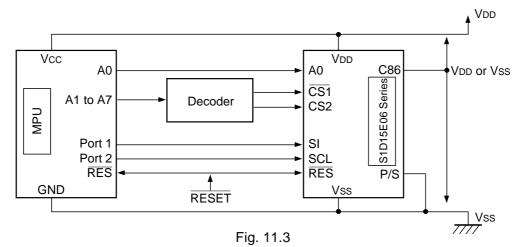


Fig. 11.2

(3) Serial interface



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12. CONNECTION BETWEEN LCD DRIVERS (Reference example)

You can easily expand the liquid crystal display area using the S1D15E06 series as a multi-chip. In this case, use the same model as the master and slave systems.

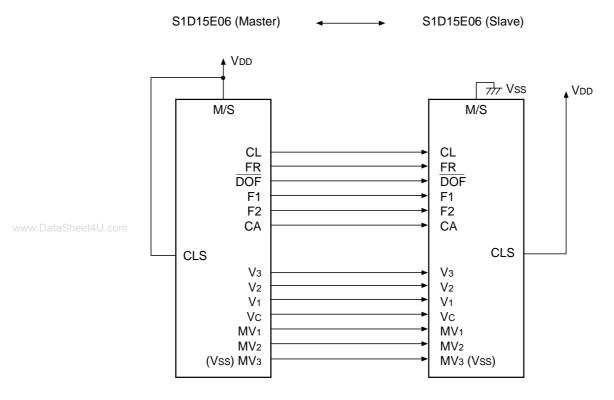
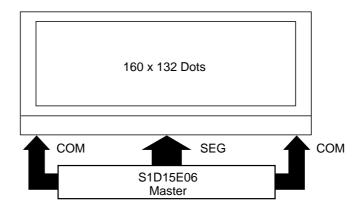


Fig. 12 Master/slave connection example (S1D15E06)

13. LCD PANEL WIRING (Reference example)

You can easily expand the liquid crystal display area using the S1D15E06 series as a multi-chip. In the case of multi-chip configuration, use the same models.

(1) Single chip configuration example



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Fig. 13.1 Single chip configuration example (S1D15E06)

(2) Double chip configuration example

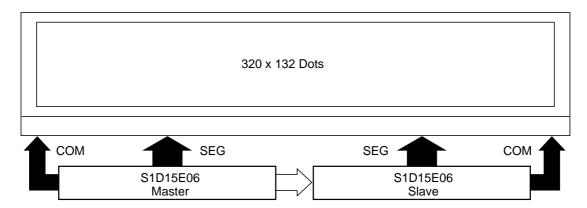
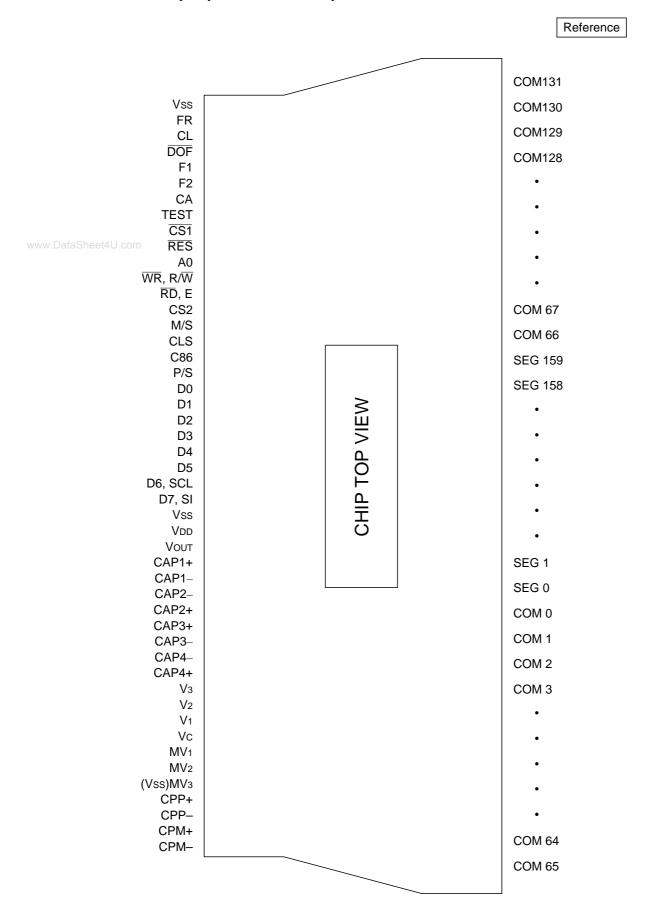


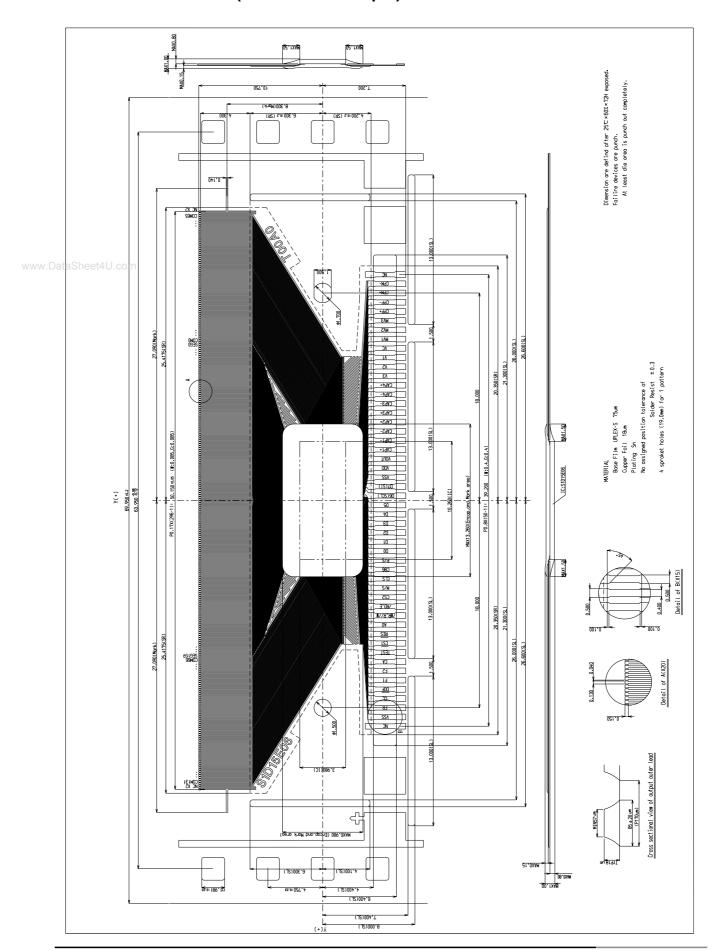
Fig. 13.2 Double chip configuration example (S1D15E06)

14. S1D15E06T00A*** TCP PIN LAYOUT

Note: This does not specify the TCP outside shape.



15. TCP DIMENSIONS (Reference example)



16. CAUTIONS

Cautions must be exercised on the following points when using this Development Specification:

- 1. This Development Specification is subject to change for engineering improvement.
- 2. This Development Specification does not guarantee execution of the industrial proprietary rights or other rights, or grant a license. Examples of applications described in This Development Specification are intended for your understanding of the Product. We are not responsible for any circuit problem or the like arising from the use of them.
- 3. Reproduction or copy of any part or whole of this Development Specification without permission of our company, or use thereof for other business purposes is strictly prohibited.

For the use of the semi-conductor, cautions must be exercised on the following points:

[Cautions against Light]

The semiconductor will be subject to changes in characteristics when light is applied. If this IC is exposed to light, operation error may occur. To protect the IC against light, the following points should be noted regarding the substrate or product where this IC is mounted:

- (1) Designing and mounting must be provided to get a structure which ensures a sufficient resistance of the IC to light in practical use.
- Un the inspection process, environmental configuration must be provided to ensure a sufficient resistance of the IC to light.
 - (3) Means must be taken to ensure resistance to light on all the surfaces, backs and sides of the IC